# TH-55AI/E SERVICE MANUAL

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Photo is TH-55AT.

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DISASSEMBLY FOR REPAIR 2
CIRCUIT DESCRIPTION 4
SEMICONDUCTOR DATA 11
DESCRIPTION OF COMPONENTS
PARTS LIST
DISASSEMBLY 30
PACKING
ADJUSTMENT 32
PC BOARD VIEWS/CIRCUIT DIAGRAM
AVR UNIT (X43-3020-11)
IF UNIT (X58-3210-01) 37
MIC AMP UNIT (X58-3370-XX)
AF AMP UNIT (X58-3380-00)
APC UNIT (X59-3420-00)
PLL UNIT (X58-3360-00)
VCO UNIT (X59-3470-00)
SWITCH UNIT (X41-3070-XX)
BPF UNIT (X59-3430-00)
SIGNALING UNIT (X52-3130-00)
CONTROL UNIT (X53-3150-XX)
TX-RX UNIT (X57-3250-XX)
SCHEMATIC DIAGRAM
BLOCK DIAGRAM 51
LEVEL DIAGRAM
TERMINAL FUNCTIONS 53
BC-9 (BATTERY CHARGER) 53
BC-10 (COMPACT CHARGER) 54
BC-11 (RAPID CHARGER)
BT-6 (AAA MANGANESE/ALKALINE BATTERY CASE) 65
DC-1 (DC ADAPTER)
HMC-2 (HEAD SET WITH VOX & PTT)
PB-5/6/7/8/9 (Ni-Cd BATTERY)
SC-17/18/19 (SOFT CASE)
SMC-31 (SPEAKER MICROPHONE)
TSU-6 (CTCSS UNIT)
MB-5 (MOBILE BRACKET)
WR-1 (WATERPROOF CASE)
SPECIFICATIONS BACK COVER

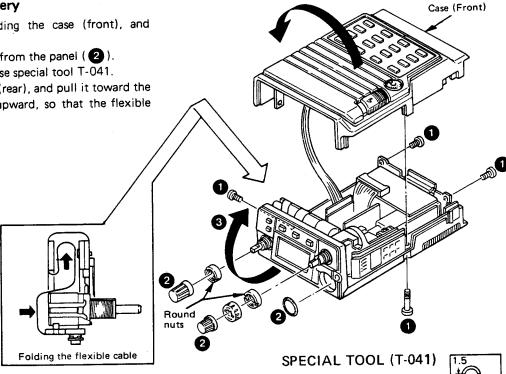


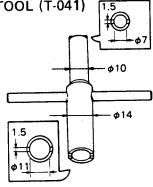
# **DISASSEMBLY FOR REPAIR**

## Replacing the Lithium Battery

- 1. Remove the 4 screws holding the case (front), and remove it (1).
- Pull out the knobs and rings from the panel (2).
   To remove the round nuts, use special tool T-041.

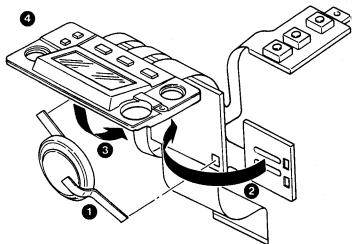
3. Hold the panel by the case (rear), and pull it toward the front by slightly lifting it upward, so that the flexible cables come out (3).





T-041 Double-ended nut spanner

4. After replacing the lithium battery, fold the flexible cables as shown in the illustration (4).





# **DISASSEMBLY FOR REPAIR**

### Removing the TX-RX Unit

Case (Front) Remove the screws in the order of the numbers shown in the illustration, and then disconnect the connectors and flexible cables; now the TX-RX Unit can be taken out. When the shielding cover is to be removed while leaving the TX-RX Unit attached to the case (rear), it is not necessary to remove the screws numbered (14) and after. **AVR** Unit Shielding cover TX-RX Unit

Case (Rear)

## FREQUENCY CONFIGURATION

The TH-55 uses a PLL synthesizer system and a digital VFO that is capable of covering a frequency range of 1258 MHz to 1299.9875MHz in 12.5kHz or 25kHz increments.

Its receiver system configuration is based upon double super-heterodyne operating principles with a first intermediate frequency (IF) of 59.7MHz and a second intermediate frequency of 455kHz.

An incoming signal from the antenna is mixed with the first local oscillator signal to produce the first intermediate frequency of 59.7MHz. The first intermediate frequency is then mixed with the second local oscillator frequency of 59.245MHz to produce the second intermediate frequency of 455kHz.

The transmitter system signal is obtained by doubling the oscillating frequency of the VCO. The signal is then amplified by a linear amplifier and fed to the antenna.

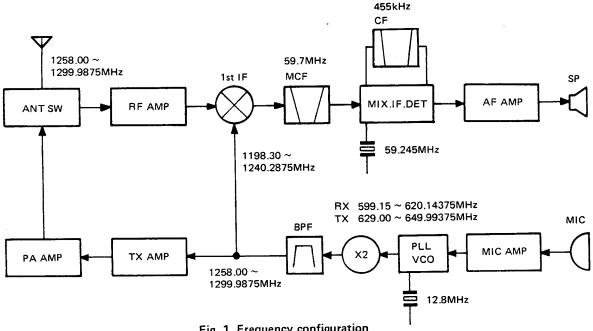


Fig. 1 Frequency configuration

#### RECEIVER SYSTEM

### General

An incoming signal from the antenna passes through a low-pass filter and an antenna switch and enters the frontend section. The signal is amplified by an RF amplifier composed of Q6 and Q7: 2SC4095. Undesirable band components are attenuated by helical coils L12 and L13. The processed signal is then mixed with the doubled VCO frequency to produce the first intermediate frequency of 59.7MHz. The signal, in the from of the first intermediate frequency, then passes through the two monolithic crystal filter (MCF) stages for further elimination of undesirable signals. After passing through the MCF stages, the target signal enters IC1: TK10486MT1(B,C) located inside the IF unit and is mixed with the second local oscillator frequency to produce the second intermediate frequency of 455kHz. The 455kHz IF signal passes through ceramic filter (CF1) and re-enters IC1 for additional amplification and demodulation. The output derived from IC1 is then amplified by the audio frequency (AF) amplifier and fed to the speaker.

ltem	Rating		
Norminal center frequency (fo)	59.700MHz		
Pass bandwidth	± 12.5kHz or more at 3dB		
Attenuation bandwidth	±35kHz or less at 25dB ±100kHz or less at 60dB		
Guaranteed attenuation	70dB or more within ± 1MHz 80dB or more within ± 890 ~ 930kHz Spurious : 40dB or more within fo ~ fo + 500kHz		
Ripple	2dB or less		
Insertion loss	4dB or less		
Terminal impedance	560Ω ± 5% / 1.5pF ± 0.1pF		

Table 1 MCF (L71-0280-05) (TX-RX unit XF1, XF2)

İtem	Rating			
Center frequency of 6dB bandwidth (fo)	455kHz ± 1.5kHz			
6dB bandwidth	± 7.5kHz or more			
40dB bandwidth	± 15kHz or less			
Ripple	1.5dB or less (455kHz ± 1.5kHz)			
Guraranteed attenuation	27dB or more within fo ± 100kHz			
Insertion loss	6dB or less			
Terminal impedance	1.5kΩ			

Table 2 Ceramic filter (L72-0362-05) (IF unit CF1)



### • Squelch and Mute Circuit

This unit has the T.ALT (Tone Alert) function to produce two muting signals. When a signal is received while the T.ALT function is ON, only a beep tone is sounded.

The microprocessor determines existing conditions and

provides muting signals MU1 and MU2 as necessary. The conditions for various muting operations are listed in table 3. When the microprocessor outputs a logical high, muting takes place.

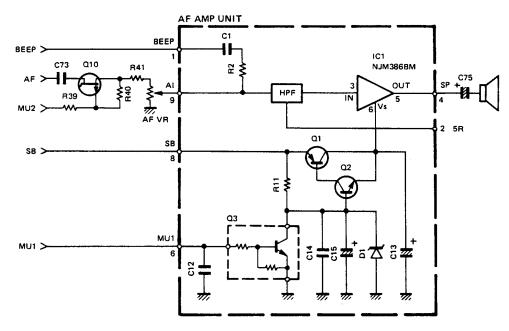


Fig. 2 Mute circuit

	Condition Transmission				
Transmissio					
	Normal	When Squelch is ON	Н	Н	
	operation T.ALT operation	When Squelch is OFF	L	L	
Reception		Waiting for Signal	Н	Н	
		Signal is Received (T.ALT operating)	L	Н	

Muted when the level is a logic "H".

Table 3 Muting conditions

### S-Meter Circuit

The signal used to drive the S-meter (signal strength meter) is taken from pin 12 by detecting the output from the IF amplifier IC1: TK10486MT1(B,C) located in the IF unit. This signal is then directly applied to pin 14 of the microprocessor and is used to control the S-meter section of the liquid crystal display (LCD). Since its display segments operate in pairs, signal strength can be indicated in six levels.

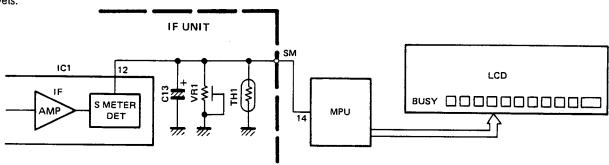


Fig. 3 S-meter circuit

# TH-55AT/E

# CIRCUIT DESCRIPTION

#### • RIT Circuit

The RIT circuit achieves a frequency deviation of over ±5kHz by varying the frequency of crystal oscillator X1, which serves as a reference frequency oscillator for the PLL circuit.

During receive, the transistor on the VR1 side, one half of Q2: FMG2, is turned OFF and the other half is turned ON. Since the reverse bias applied to D1: MA363 of the PLL unit can be varied by means of VR2 within a range of over  $\pm 1V$ , the frequency of the first local oscillator can be varied in excess of  $\pm 5kHz$ .

During transmission, the half of Q2 on the VR1 side is turned ON and the other half is turned OFF. This condition inhibits VR2, and as a result, the transmission frequency is fixed as preset by VR1.

Excellent frequency stability is achieved by virtue of thermistor TH1, which temperature-compensates the reference-frequency crystal oscillator.

#### TRANSMITTER SYSTEM

#### General

The transmitter frequency is obtained by doubling the oscillation frequency of the voltage-controlled oscillator (VCO) in the PLL circuit.

Modulation is achieved by varying the oscillation frequency of the VCO by means of the microphone amplifier's output, which is directly applied to the variable-capacitance (varicap) diode located in the VCO circuit.

The output derived from the VCO is amplified, first in the drive stage, then by the RF power module where the signal is amplified to the required power level and fed to the antenna.

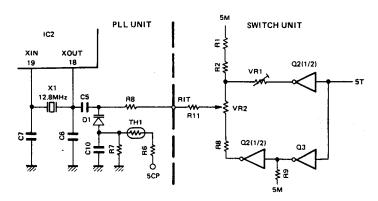


Fig. 4 RIT circuit

#### Modulation Circuit

The signal from the microphone enters the MIC amplifier unit where it is amplified and then limited. The output signal from the limiting amplifier passes through the splatter filter and reaches the MOD terminal by way of the microphone gain control. The signal enters the VCO unit and is applied to varicap diode D2: MA360 in the VCO circuit, producing variable reactance phase modulation.

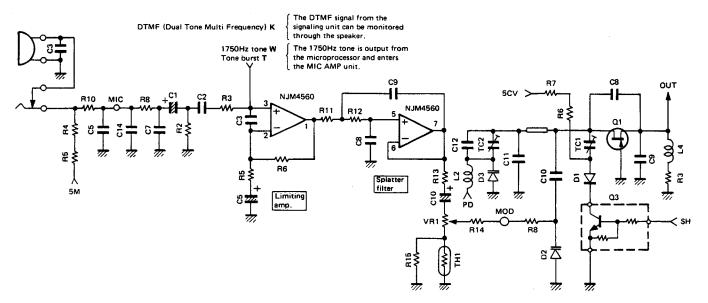


Fig. 5 Modulation circuit

#### Drive and Final Circuits

The modulated signal from the VCO is doubled in frequency, passes through the band-pass filter (BPF) and the transmit/receive switch composed of D1 and D2: MA77, and enters the drive stage. In the drive stage, the signal is amplified by a two-stage amplifier to approximately +9 dBm. The Automatic Power Control (APC) voltage is used to vary the collector voltage of the first-stage of the power module in order to control the output. The output from the drive circuit is further amplified by the RF power module and fed to the antenna through the antenna switch.

### Hi/Low Switching Circuit

The TH-55 is equipped with a transmit power switch to allow selection of a high output power of 1W (with a power source voltage of 9V) or a low output power of 0.1W.

This switch is used to turn ON/OFF potentiometers VR1 and VR2 in the APC unit, which in turn change the base voltage of Q2. As a result, the CTL voltage is changed.

#### APC Circuit

The APC circuit is designed to deliver stable transmitter output power. This circuit operates by detecting the standing wave of the final module's output with the help of a directional coupler. The signal obtained from this coupler is used to provide, automatic power control by controlling Q2, Q3, and Q4 in the APC unit, which in turn vary the power supply voltage of the power module's first stage.

By virtue of the above control operation, stable RF output power can be generated from the final module. Furthermore, a relatively constant current to the final module that is independent of load variations can be provided.

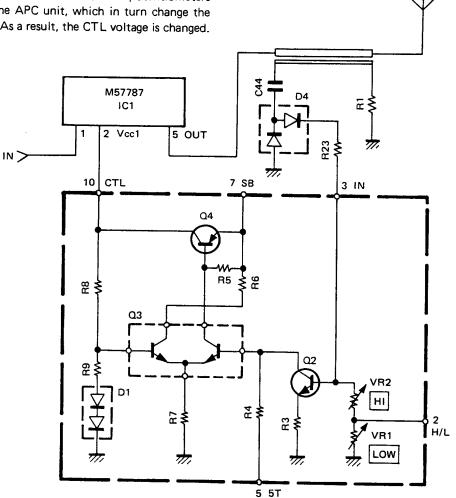


Fig. 6 APC and HI/LOW switching circuit

### POWER SUPPLY CIRCUIT

The individual circuits that make up the TH-55 are operated by power supply voltage SB and one or more of the following voltages, which are obtained from the power supply voltage SB: 5V (5T) transmit B+, 5V (5R) receive B+, 5V (5C) common B+, and 5V (5M) microphone/microprocessor B+.

The signal that appears on the TX terminal is used to switch between 5T and 5R. Since pin 29 of the microprocessor is at a logical low during transmission, transistor Q4:

2SA1313(Y) turns ON and 5C is supplied at the 5T terminal.

During reception, pin 29 of the microprocessor is open (logical high), transistor Q4: 2SA1313(Y) turns OFF and, in turn, Q5 and Q6 turn ON supplying 5C at the 5R terminal.

5C is obtained from, 5V three-terminal regulator IC1 : LP2950CZ, a differential amplifier Q2 : FMW1 and Q1 : 2SB1182F5(Q).

The 5V output of regulator IC1 is used to power the microprocessor and the microphone amplifier circuit.

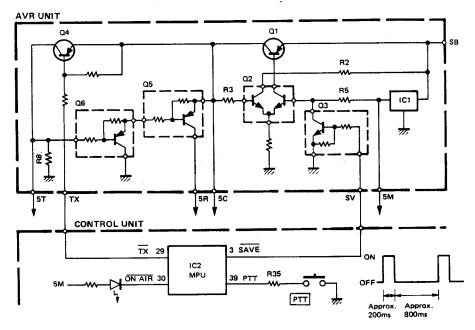


Fig. 7 Power supply circuit

### • Battery-save and Automatic Power OFF

The TH-55 is equipped with a battery-save function and an automatic power-off function to save battery power during standby reception. The microprocessor :  $\mu$ PD75108AG places a control signal on its SAVE pin (pin 3), which activates the battery-save function or the automatic power-off function depending on existing conditions. When this signal is present, all power supplies are turned off except

the 5V (5M) that is used for powering the microprocessor and the microphone amplifier circuit. When the battery-save function is operative, it alternately switches between the ON (normal) state for approximately 200msec. and the OFF (save) state for approximately 800msec.

The power-off function sustains the above OFF state, in which the current consumption is reduced to approximately 5mA.

	Battery-saving operation	Auto power-off operation	To cancel battery-save and auto power-off operation		
Operation starting time	10 seconds after the closure of the squelch circuit and if no key has been pressed in the interim.	60 minutes after the closure of the squelch circuit and if no key has been pressed during this period. (A beep tone sounds for 5 seconds after 59 minutes.)	Turn the power switch ON again while holding down the "MHz" key.		
Resetting	Receive an incoming signal.  Open the squelch function.  Or press a key.	Press the MONI key. Turn the power switch ON again.	Turn the power switch ON again while holding down the "MHz" key.		
Display	Normal	pa OFF	APO/BS cancel mark		

Table 4 Battery-saving and automatic power-off operation conditions

and the control of th

#### PLL SYNTHESIZER SECTION

In the TH-55, a common VCO is used to obtain 40MHz for both transmission and reception.

To obtain comparison frequencies in 12.5kHz and 25 kHz increments, the 12.8MHz oscillation frequency of the reference oscillator is divided by 2048 to produce 6.25kHz. The VCO runs at half the target frequency required for use by both transmitter and receiver sections. The transmit/receive switching signal is felt on the SW1 pin 14 of IC2: JLC1075F. The output signal derived from the VCO is applied to a frequency-doubler as well as the prescaler IC1: MB501L. This IC incorporates two modular prescalers, one with a frequency division factor of 1/128 and the other with a frequency division factor of 1/129. Selection is made by way of the MC terminal. The output of the prescaler is applied to the PLL IC IC2: JLC1075F. Using these two ICs, a pulse-swallow PLL circuit configuration is created.

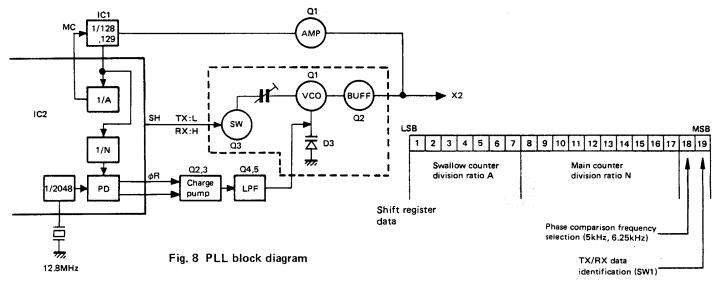
The output of the phase comparator passes through the charge pump made up of Q2 and Q3 external to the synthesizer section, then through the active low-pass filter (LPF) made up of Q4: 2SC2712(GR) and Q5: 2SC3624(L18), and is applied to varicap diode D3: MA360 in the VCO section.

These PLL division ratios and frequencies are expressed by the following equation:

Overall division ratio, M = A + 128N,

where A is the swallow counter division ratio, and N is the main counter division ratio.

A and N are received from the microprocessor as serial data and take on different values between transmission and reception. For this reason, the overall division ratio, M, calculated for transmit is different from its counterpart in receive. The data is stored in a 19-bit shift register.



MICROPROCESSOR & PERIPHERAL CIRCUITS

#### ● Tone Alert Function (T.ALT)

The T.ALT function is designed to alert the user by sounding a 5-second beep tone and by flashing the bell (tone alerm) indicator when an incoming signal is received during standby. Terminals S2 and I1 are shorted by pressing the T.ALT switch and the microprocessor senses this switching action and outputs logical high signals on its MU1 and MU2 terminals.

The output on MU1 turns off the power supply (VS) to the AF amplifier, while the output on MU2 turns off the input signal to the AF amplifier by means of Q10: 2SJ144 (GR)

When an incoming signal is received from the antenna, terminal SC of the IF unit goes from low to high, and this activates the BUSY pin of the microprocessor. When the microprocessor receives this signal, it pulls MU1 low to turn on the power supply of the AF amplifier.

At the same time, the microprocessor outputs a beep tone on its BEEP terminal. This signal is amplified by the AF amplifier and output by speaker SP.

Fig. 9 PLL data configuration

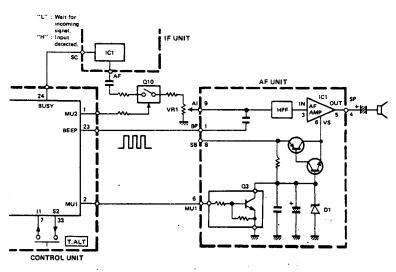


Fig. 10 T.ALT functional circuit



## Reset and Backup Circuits

In the reset and backup circuits, various operations are performed through the detection of voltage 5M. Resetting is done by applying a logical low pulse, which is produced by C1 and Q1: 2SC2712(Y), to the RESET terminal of the microprocessor. Backup operations are controlled when the 5M voltage drops to approximately 4.5V (4.3V to 4.6V). When this occurs the output of IC3: S8054ALR goes low.

The microprocessor senses this low state at its VF terminal and goes into the backup mode.

When the 5M voltage rises abruptly, the reset circuit made up of C1 and Q1 resets the microprocessor. When the 5M voltage rises gradually, the reset operation is performed within the microprocessor by the detection of a voltage rise that takes place as the output of IC3 changes from low to high.

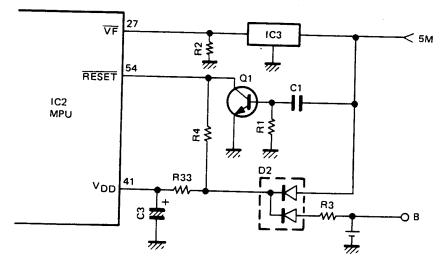


Fig. 11 Reset and backup circuit

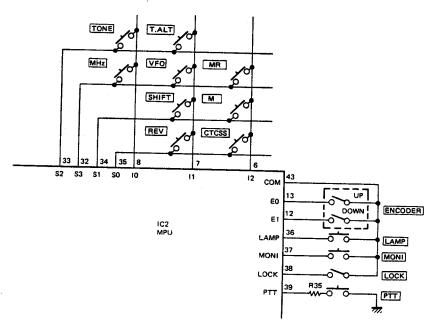


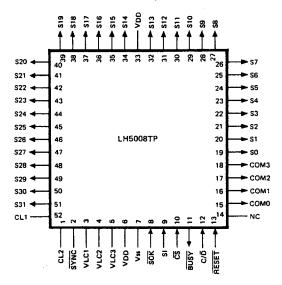
Fig. 12 Keyboard



# **SEMICONDUCTOR DATA**

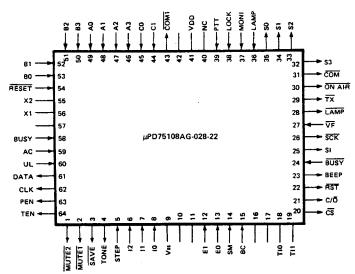
### LH5008TP (Control unit IC1)

### • Terminal connection diagram



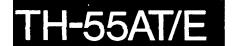
## μPD75108AG-028-22 (Control unit IC2)

### • Terminal connection diagram



#### • Terminal functions (LH5008TP)

Pin No.	Name	1/0	Function			
. 1	CL2	-	Internal clock oscillation resistance pin.			
2	SYNC	<b>—</b>	Not used.			
3, 4	VLC1, VLC2	-	LCD driver power supply.			
5	VLC3	_	Ground.			
6	VDD	_	+5V power supply.			
7	Vss	-	Ground.			
8	SCK	1	Shift clock input.			
9	SI	ı	Serial data input.			
10	ঙ্গ	1	Enable input. "L": Data input enabled, "H": Contents of the memory are output			
11	BUSY	0	Data input control. "L": Inhibit, "H": Permit			
12	C/D	1	Input data indentification input. "L" Data, "H" : Command			
13	RESET	ı	Reset input.			
14	NC	T -				
15 ~ 17	COM0 ~ COM2	0	Common drive output.			
18	сомз	0	Not used.			
19 ~ 32	S0 ~ S13	0	Segment drive output.			
33	VDD	-	+5V power supply.			
34 ~ 45	S14 ~ S25	0	Segment drive output.			
46 ~ 51	S26 ~ S31	0	Not used.			
52	CL1	T -	Internal clock oscillation resistance pin.			



# **SEMICONDUCTOR DATA**

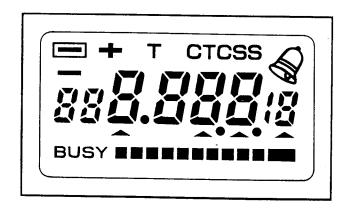
## • Terminal functions (μPD75108AG-028-22)

		<del>,</del>	During any	
Pin No.	Name	1/0	During save	Function
1	MUT2	10	<u> </u>	AF input line control. "L": ON, "H": OFF
2	MUT1	0	H	AF amplifier power control. "L" : ON, "H" : OFF
3	SAVE	<u> </u>	Н	Power save control. "L": ON, "H": OFF
4	TONE	<u> </u>	L	Tone output. During transmit, 1750Hz. T, W Type
5	STEP	1		Step control. "L": ON, "H": OFF
6	12			Key matrix input, M, CTCSS, MR
7	11	T T	<u> </u>	Key matrix input. VFO, T. ALT, SHIFT, REV
8	10	1	-	Key matrix input. MHz, TONE
9	· Vss			Ground.
10, 11	-		-	Ground.
12	E1.	ı	_	Encoder input, DOWN
13	E0	1	-	Encoder input. UP
14	SM	I	_	S meter input.
15	BC	1	-	Battery voltage check.
16, 17	<u> </u>	-	-	Ground.
18	TIO	_	_	Ground.
19	Ti1	_	_	Ground.
20	ĊŚ	0	Н	LCD driver control output.
21	C/D̄	0	Н	LCD driver control output.
22	RST	0	Н	LCD driver control output.
23	BEEP	0	L	Square wave output when BEEP is on.
24	BUSY	1		LCD driver control output.
25	SI	0		LCD driver control output.
26	SCK	0		LCD driver control output.
27	VF VF	1		
28	LAMP	0		Perform backup operation when the 5M voltage drops.
29	TX		H	Lamp ON/OFF control. "L": ON, "H": OFF
30	<u></u>	0	Н	Transmit/receive switching. "L": Transmit, "H": Receive
	ON AIR	0	Н	ON AIR display output. "L": ON, "H": OFF
31	COM	0	L	"L": normal, "H": during save or backup.
32	S3 C0	0	L	Key matrix output. MHz, VFO, MR
33	S2	0	L	Key matrix output. TONE, T.ALT
34	S1	0	L	Key matrix output. M, SHIFT
35	S0	0	L	Key matrix ourpur. CTCSS, REV
36	LAMP	1	-	Lamp switch control. "L": SW ON, "H": SW OFF
37	MONI	1	-	Monitor switch control. "L": SW ON, "H": SW OFF
38	LOCK	1		Lock switch control. "L": SW ON, "H": SW OFF
39	PTT	1		PTT switch control. "L": SW ON, "H": SW OFF
40	NC	-	-	Open.
41	VDD_			+5V power supply.
42			_	Ground.
43	COM1	0	L	
44	C1	1	Н	Display switching, "L": Normal display, "H": Channel display
45	CO	1	_	VHF/UHF switching. "L" : VHF, "H" : UHF
46 ~ 49	A3 ~ A0	1	_	Destination.
50 ~ 53	83 ~ B0	ı	-	Destination.
54	RESET	1	_	System reset.
55	X2	_		
56	X1	_	_	
57		_	_	Open.
58	BUSY		_	Busy control. "L" : Open, "H" : Busy
59	AC		-	Tone squelch control output, "L": No match, "H": Match
60	UL	<u>'</u>	<del>-</del>	Unlock output: "L" : Lock, "H" : Unlock
61	DATA	0	Ĺ	PLL, TONE data.
62	CLK	0	L	PLL, TONE clock.
63	PEN	0		
			L	PLL enable.
64	TEN	0	L	CTCSS enable.

# **SEMICONDUCTOR DATA**

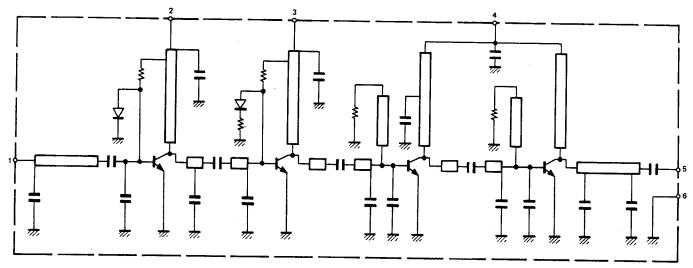
# FTD8608 (Control unit LCD)

All lighting



# M57787 (TX-RX unit IC1)

## • Equivalent circuit



## • Electrical characteristics

item	Symbol	Rating				
	Symbol	MIN.	TYP.	YP. MAX.	Unit	Condition
Output power	Po	1.5	1.7		w	Vcc1 = Vcc2 = Vcc3 = 7.2V
Total efficiency	ηT	28	30	1	. %	f = 1.24 ~ 1.3GHz
2nd spurious			<u> </u>	-30	dB	Pin = 7mW
Input SWR	ρin	<b>†</b>		2.5	_	ZG = ZL = 50Ω
Output SWR	ρout		1.5		_	Tc = 25°C

### Maximum rating

Item	Symbol	Condition	Rating	Unit
Operating voltage	Vcc1, 2		9	V
Operating voltage	Vcc3		16	v
Current consumption	Icc		1.5	A
Input power	Pin	ZG = ZL = 50Ω, Vcc1≦8V, Po≦3W	10	mW
Output power	Po	ZL = 50Ω	5	w
Operating case temperature	Tc (op)		-20 ~ +100	°C
Storage temperature	Tstg		-40 ~ +110	°C

1; Input

2 : Pre-drive + B

3 : Bias + B

4 : Final + B

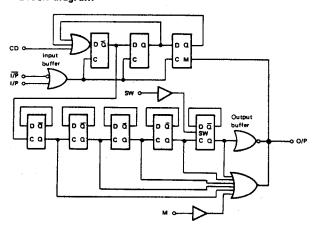
5 : Output 6 : GND (Fin)

# TH-55AT/E

# **SEMICONDUCTOR DATA**

## MB501L (PLL unit IC1)

### Block diagram



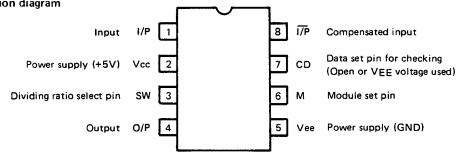
#### • Function table

sw	М	Division ratio
Η	Н	64
H	L	65
L	н	128
L	L	129

SW: H; Vcc, L; Open

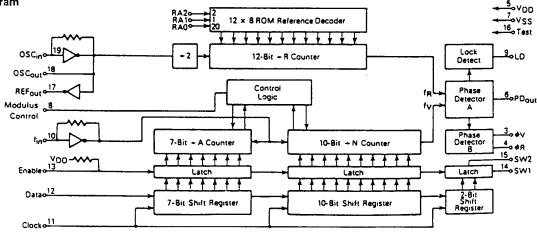
M : H; 2.0V~Vcc, L; VEE~0.8V





### JLC1075F (PLL unit IC2)

### • Block diagram



e our also have been appeared by a few hours of the confidence of

#### Terminal connection diagram

		_
RA1	1 . :	20 ===RA0
8A2Œ	2 1	9⊨osc <sub>in</sub>
<b>•</b> ∨ <b></b> ⊏	3	8⊨osc <sub>out</sub>
∳R⊂	4 1	7 PEFout
VD0⊂	5 1	6 Test
PO <sub>out</sub> ⊂	6 1	5 == SW2
∨ss⊏	7 1	4 - SW1
Mod Control □	8 1	3 Enable
roci	9 1	2 Data
fin C	10 1	Clock

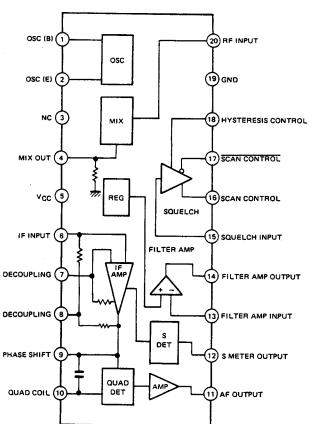
#### • Total division ratio

Refere	nce addre	ess code	Total
RA2	RA1	RA0	division ratio
0	0	0	8
0	0	1	64
0	11	0	128
0	1	1	256
1	0	0	1160
1	0	1	2560
1	1	0	1024
1	1	1	2048

# SEMICONDUCTOR DATA/DESCRIPTION OF COMPONENTS

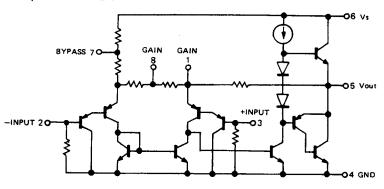
### TK10486MT1 (IF unit IC1)

### Block diagram



## NJM386BM (AF AMP. unit IC1)

### • Equivalent circuit



#### • Electrical characteristics

item	Comphal	Rating			11		
T (BIT)	Symbol	MIN.	TYP.	MAX.	Unit	Condition	
Supply voltage	Vs	4	-	18	V		
Output power	Pour	500	850	-	mW	Vs = 9V, RL = 8Ω, THD = 10%	
Voltage gain	Av		46		đВ	f = 1kHz, Between 1 and 8 : Connect capacitor (10µF).	
Bandwidth	BW		600		kHz	Between 1 and 8 : Open.	
Distortion	THD		0.2		%	f = 1kHz, Pour = 125mW,	
Input resistance	RIN		50		kΩ	RL=8Ω	

### **Description of Components**

### TX-RX UNIT (X57-3250-XX)

Component	Part No.	Operation/Condition/Compatibility
Q1	DTA114YU	Unlock detection switch , low when locked.
Q2	2SC4093	Frequency multiplication (x 2) and amplification.
Q3, 5	2SC4093	Drive-stage amplifier.
Q4	DTC144EU	Transmission/reception HET selection switch; ON during reception.
Q6, 7	2SC4095	RF amplifier.
Q8	2SC3585	RX 1st mixer.
Q9	2SC2714(O)	1st IF amplifier, 59.7MHz.
Q10	2SJ144(GR)	AF muting switch (MU2).
IC1	M57787	Power amplifier.
IC2	MD-004	Antenna switch.
D1, 2	MA77	Transmission/reception HET selection switch.
D3	DA204K	Bias setting for Q5.
D4	HSM88AS	Power detection.
D5	MA110	Backflow prevention.

# H-55AT/E

# **PARTS LIST**

CAPACITORS

CC 45 TH 1H 220 J 1 2 3 4 5 6

CC45, -Color\* Capacitor value

1 0 3 =  $0.01\mu$ F

1 = Type ..... ceramic, electrolytic, etc. 4 = Voltage rating

 $0 \ 1 \ 0 = 1pF$ 0.0 = 10pF

2 2 0 = 22pF 1st number | Multiplier

2 = Shape .....round, square, etc. 3 = Temp, coefficient

5 = Value 6 = Tolerance

0 1 = 100pF

2nd number

#### • Temperature Coefficient

1st Word	С	L	Р	R	S	Т	U
Color*	Black	Red	Orange	Yellow	Green	Blue	Violet
ppm/°C	0	-80	-150	-220	-330	-470	-750

1	U	2 =	100001	· = 0.001µ	Г

2nd Word	G	Н	J	K	L
ppm/°C	± 30	± 60	± 120	± 250	± 500

Example CC45TH = -470 ± 60 ppm/°C

### Tolerance

Code	С	D	G	J	K	М	×	Z	Р	No code
(%)	± 0.25	± 0.5	± 2	± 5	± 10	± 20	+ 40	+ 80	+ 100	More 10µF-10~+50
							20	-20	0	Less 4.7μF-10~+75

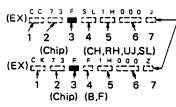
Code	В	C	٥	F	G
(pF)	± 0.1	± 0.25	± 0.5	± 1	± 2

Less than 10 pF

#### Rating voltage

2nd word 1st word	A	В	С	D	E	F	G	н	J	к	٧
0	1.0	1.25	1.6	2.0	2.5	3.15	4.0	5.0	6.3	8.0	-
1	10	12.5	16	20	25	31.5	40	50	63	80	35
2	100	125	160	200	250	315	400	500	630	800	
3	1000	1250	1600	2000	2500	3150	4000	5000	6300	8000	-

### • Chip capacitors



-£=3 → Refer to the table above.

## RESISTORS

### • Chip resistor (Carbon)

• Carbon resistor (Normal type)

- 1 = Type ..... ceramic, electrolytic, etc.
- 2 = Shape ..... round, square, etc.
- 3 = Dimension
- 4 = Temp. coefficient
- 5 = Voltage rating
- 6 = Value
- 7 = Tolerance.

### Dimension

Dimension code	L	W	Т
Empty	5.6 ± 0.5	5.0 ± 0.5	Less than 2.0
Ε	3.2 ± 0.2	1.6 ± 0.2	Less than 1.25
F	2.0 ± 0.3	1.25 ± 0.2	Less than 1.25

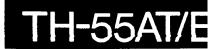
#### Dimension

Dimension code	L	W	T	Wattage
Ε	3.2 ± 0.2	1.6 ± 0.2	0.57	28
F	2.0 ± 0.3	1.25 ± 0.2	0.45	2A

#### Rating wattage

Cord	Wattage	Cord	Wattage	Cord	Wattage
2A	1 /10W	2E	1/ 4W	3A	1W
2B	1/ 8W	2H	1/ 2W	3D	2W
2C	1/ 6W				





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Ref. No.	Address		Parts No.	Description		Re-
参照番号	位置	Parts 新	部品番号	部品名/規格		marks 備考
			TH	I-55AT/E	•	<b>.</b>
1 2 2 3 4	3B 1A 1A 2B 2B	* * *	A01-1050-02 A02-0846-03 A02-0847-03 A11-0406-04 A11-0407-04	METALLIC CABINET(REAR) PLASTIC CABINET(FRØNT) PLASTIC CABINET(FRØNT) SUB CHASSIS ASSY(ENCODER) SUB CHASSIS ASSY(VØL)	AT E	
5 6	2A 3B		A20-2625-03 A40-0621-04	PANEL ASSY BOTTOM PLATE		
7 7 8 9	3B 3B 3B 1C 3B	* *	840-3806-04 840-3807-04 842-2437-04 842-3325-04 801-0664-03	MODEL NAME PLATE MODEL NAME PLATE LABEL (SERIAL) LABEL ESCUTCHEON	AT E	
11 11 12 13 14	1B 1B 2C 2B 2B	*	B03-0547-04 B03-0550-04 B09-0309-04 B10-0698-04 B11-0449-04	DRESSING PLATE (DTMF) DRESSING PLATE CAP (SP,MIC) FRONT GLASS FILTER	AT E	
15 15 16	1D 1D 1D	*	B46-0410-20 B46-0419-00 B50-8224-00	WARRANTY CARD WARRANTY CARD INSTRUCTION MANUAL	AT E(W)	
19 20 21	38 38 38		E23-0494-14 E23-0605-14 E04-0168-05	TERMINAL (-) TERMINAL (+) BNC RECEPTACLE		
22 23 25 26 27	2B 1A 2A 2B 3B	* *	F11-1100-03 F19-0650-04 F20-0594-04 F20-0600-04 F20-1006-04	SHIELDING COVER(TX-RX) BLIND PLATE (MIC) INSULATING SHEET(CONTROL) INSULATING SHEET(VR) INSULATING SHEET(TX-RX)		
28 29 -	3B 3B		F20-1008-04 F29-0435-05 F20-0587-04	INSULATING SHEET(BOTTOM PLATE) INSULATOR (BELT HOOK) INSULATING SHEET(LITHIUM BATT)		
33 34 35 36 37	2A 1A 2A 3B 3B	*	G02-0505-05 G10-0657-04 G10-0670-04 G13-0852-04 G16-0514-04	SPRING (VØL,ENCØDER) FELT (SPEAKER) NØN-WØVEN FABRIC(CASE BØTTØM) CUSHIØN SHEET		
41 42 43 44 44	1D 2D 20 30 30 30	*	H11-0808-14 H13-0801-04 H13-0818-04 H01-8174-02 H01-8175-02	POLYSTYRENE BOARD PROTECTION BOARD PROTECTION BOARD ITEM CARTON BOX ITEM CARTON BOX	AT E	
45 46 48	3D 1D 1C	*	H10-2643-02 H21-0715-04 H25-0085-04	POLYSTYRENE FOAMED FIXTURE PROTECTION SHEET PROTECTION BAG (100X200)		
49 50 51 52 53	3B 1A 1A 1A 2C	*	J19-1426-03 J21-4223-04 J21-4234-04 J21-4235-04 J29-0424-04	HØLDER (PØWER TERMINAL) MØUNTING HARDWARE(CASE BØTTØM) MØUNTING HARDWARE(SPEAKER) MØUNTING HARDWARE(CASE SIDE) BELT HØØK		
54 55	1A 1A	*	J30-0550-04 J31-0526-04	SPACER (SPEAKER) MIC SPACER		

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# TH-55AT/E

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参照番号	位 置	新	部品番号	部品名/規格	仕 向情	
56 57	2A 2C		J69-0311-05 J69-0312-04 J99-0311-04	RING (BNC) HAND STRAP ADHESIVE SHEET (LITHIUM BATT)	Ĉ.	
60 61 62 63 64	38 18 2A 2A 2A	*	K27-0499-04 K27-3029-04 K29-3096-04 K29-3097-04 K29-3098-04	KNOB (LO/HI) KNOB (F.LOCK) KNOB (VOL) KNOB (SQL) KNOB (ENCODER)		
65 66 67 68 69	38 38 2A 38 1A		K29-3100-04 K29-3102-03 K29-3103-04 K29-3104-04 K29-3105-04	KNØB         (RELEASE)           KNØB         (PTT)           KYE TØP         (MHZ, MCH)           KYE TØP         (REV, M)           KYE TØP         (DTMF)	АТ	
70	18	*	K29-3141-04	KNOB (RIT)		
81 A B C D	2A 1B 2B 3B 1B,2B		N14-0534-04 N30-2020-41 N32-2012-41 N33-2005-45 N35-2004-41	NUT (VØL,ENCØDER) PAN HEAD MACHINE SCREW FLAT HEAD MACHINE SCREW ØVAL HEAD MACHINE SCREW(BNC) BINDING HEAD MACHINE SCREW		
E F G H I	18 18 38 1A 28	-	N35-2006-41 N39-1450-45 N39-2040-45 N89-2006-46 N09-0663-04	BINDING HEAD MACHINE SCREW PAN HEAD MACHINE SCREW (RIT) PAN HEAD MACHINE SCREW BINDING HEAD TAPTITE SCREW(SWU SCREW (M1.7X4)	NIT)	
Ј К М <b>N</b>	3B 3A,2B 3B 3B 1A	-	N09-2022-05 N09-2023-05 N09-2024-05 N09-2025-05 N09-2026-05	SCREW (M2X4) SCREW (M2X3) SCREW (Ø2X16) SCREW (Ø1.7X3) SCREW (Ø2X3.5)		
Q	3B		NO9-2028-05	SCREW (M3X4)		
R1			RD14BB2B333J	RD 33K J 1/8W		
85 86 87	1A 2D 1A	*	T07-0251-05 -T90-0364-05 T91-0372-05	LØUDSPEAKER ANTENNA MICRØPHØNE		
87 87 89 90 -	2D 2D 2D 2D		W09-0382-15 W09-0387-05 W09-0388-05 W09-0507-05 W09-0394-05	BATTERY CHARGER(120V) BATTERY CHARGER(240V) BATTERY CHARGER(220V) BATTERY ASSY (PB-6) LITHIUM BATTERY	AT E(T) E(W)	
95 95 96 97 98	1A 1A 1B 1A 2A	* * * *	X41-3070-00 X41-3070-61 X43-3020-11 X52-3130-00 X53-3150-11	SW UNIT SW UNIT AVR SIGNALING UNIT (DTMF) CONTROL UNIT	AT E AT AT	
98 98 99 99	2A 2A 2B 2B	* * *	X53-3150-51 X53-3150-61 X57-3250-11 X57-3250-61	CONTROL UNIT CONTROL UNIT TX.RX UNIT TX.RX UNIT	E(T) E(W) AT E	
	sv		<del></del>	KX) -00 : TH-55AT -61 : TH-55E		
C1 ,2 C3 C4		*	C92-0509-05 CC73FSL1H101J CK73EB1E104K	TANTAL 10UF 6.3WV CHIP C 100PF J CHIP C 0.10UF K		

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⚠ indicates safety critical components.

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Ref. No.	Address New		Description	Desti- Re-
参照番号	位置 新	1	部品名/規格	nation marks 仕 向 備考
C5 C6 ,7 C8 -15		CK73F81E103K CC73FSL1H101J CC73FSL1H101J	CHIP C 0.010UF K CHIP C 100PF J CHIP C 100PF J	АТ
J1 J2 W1 W2	*		PHONE JACK MIC JACK CONNECTING WIRE CONNECTING WIRE	AT
JP1 -4 JP5 R1 R2 R3		R92-1061-05 R92-1061-05 RK73FB2A182J R92-0670-05 RK73FB2A271J	JUMPER REST O 0HM JUMPER REST O 0HM CHIP R 1.8K J 1/10L CHIP R O 0HM CHIP R 270 J 1/10L	
R4 R5 R6 R7 R8		RK73FB2A182J RK73FB2A471J RK73EB2B101J RK73FB2A152J RK73FB2AB22J	CHIP R 1.8K J 1/10V CHIP R 470 J 1/10V CHIP R 100 J 1/8W CHIP R 1.5K J 1/10V CHIP R 8.2K J 1/10V	
R9 R10 R11 R12 R13		RK73FB2A473J RK73FB2A100J RK73FB2A102J R92-0670-05 RK73FB2A562J	CHIPR 47K J 1/10W CHIPR 10 J 1/10W CHIPR 1.0K J 1/10W CHIPR 0 WHM CHIPR 5.6K J 1/10W	AT
VR1 VR2	*		TRIMMING POT.(SK) POTENTIOMETER(10K)	
Q1 Q2 Q3		DTC144EK FMG2 DTC144EK	DIGITAL TRANSISTÖR DIGITAL TRANSISTÖR DIGITAL TRANSISTÖR	AT E
		AVR UNI	Г (X43-3020-11)	
C1 C2 -4 C5 C6 ,7 C8		C90-2073-05 CC73FSL1H101J C90-2053-05 CC73FSL1H101J C92-0004-05	ELECTR® 6.8UF 16WV CHIP C 100PF J ELECTR® 47UF 6.3WV CHIP C 100PF J CHIP TAN 1UF 16WV	
C9 -14 C15 C16 -20 C22 C3O -32		CC73FSL1H101J C90-2049-05 CC73FSL1H101J CC73FSL1H101J CC73FSL1H101J	CHIP C 100PF J ELECTRO 15UF 6.3WV CHIP C 100PF J CHIP C 100PF J CHIP C 100PF J	
CN1	*	E40-5165-05	PIN CONNECTOR	
L1 ,2		L92-0122-05	BEAD CORE	
R1 R2 R3 R4 R5		RK73FB2A332J RK73FB2A102J RK73FB2A472J RK73FB2A272J RK73FB2A472J	CHIP R 3.3K J 1/10V CHIP R 1.0K J 1/10V CHIP R 4.7K J 1/10V CHIP R 2.7K J 1/10V CHIP R 4.7K J 1/10V	
R6 R7 R8 R15 R16		RK73FB2A473J RK73FB2A272J RK73FB2A472J RK73FB2A124F RK73FB2A274F	CHIP R 47K J 1/100 CHIP R 2.7K J 1/100 CHIP R 4.7K J 1/100 CHIP R 120K F 1/100 CHIP R 270K F 1/100	 
IC1 Q1		-LP2950CZ-5.0 2SB1182F5(Q)	IC(V0LTAGE REGULAT0R/ +5V) CHIP TRANSIST0R	

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参照番号	位置新	部品番号	部品名/規格	仕 向 備考
02 03 04 05 06		FMW1 DTC144EK 2SA1313(Y) DTA143XK DTA144EK	DIGITAL TRANSISTØR DIGITAL TRANSISTØR CHIP TRANSISTØR DIGITAL TRANSISTØR DIGITAL TRANSISTØR	
Q8		DTC144EK	DIGITAL TRANSISTOR	
	S	IGNALING UNIT (X5	2-3130-00) TH-55AT ONLY	
C1 C2 -5 C6 C7 C8		CEO4CWOJ100M CC73FSL1H101J CK73FB1H222K CK73EB1E104K CK73FB1E103K	ELECTRO 10UF 6.3WV CHIP C 100PF J CHIP C 2200PF K CHIP C 0.10UF K CHIP C 0.010UF K	AT AT AT AT AT
C9 C10 C11 ,12 C13		C92-0003-05 C92-0009-05 CC73FSL1H101J C92-0009-05	CHIP TAN 0.47UF 25WV CHIP TAN 4.7UF 10WV CHIP C 10OPF J CHIP TAN 4.7UF 10WV	AT AT AT AT
X1		L78-0035-05	RESONATOR	AT
R1 R2 R3 R4 R5		RK73FB2A222J RK73FB2A103J RK73FB2A472J RK73FB2A122J RK73FB2A563J	CHIPR 2.2K J 1/10W CHIPR 10K J 1/10W CHIPR 4.7K J 1/10W CHIPR 1.2K J 1/10W CHIPR 56K J 1/10W	AT AT AT AT AT
R6 R7 VR1		R92-0670-05 RK73FB2A101J R12-3449-05	CHIPR O 9HM CHIPR 100 J 1/10W TRIMMING P0T.10K	AT AT AT
IC1 Q1 Q2		LR40872 2SC2712(GR) DTA114EK	IC(TØNE DIALER) CHIP TRANSISTØR DIGITAL TRANSISTØR	AT AT AT
		· · · · · · · · · · · · · · · · · · ·	50-XX) -11 : K -51 : T -61 : W	
103	2A	A33-0409-04	REFLECTOR	
C1 C2 C3 C4 C5 -7		CK73FB1E223K CK73FB1E103K C92-0010-05 CK73FB1H102K CK73FB1E103K	CHIP C 0.022UF K CHIP C 0.010UF K CHIP TAN 6.8UF 6.3WV CHIP C 1000PF K CHIP C 0.010UF K	
C11		CC73FSL1H101J	CHIP C 100PF J	
107	2A	E29-0478-04	CONNECTOR	
111	2A	J21-4220-04	MOUNTING HARDWARE	
X1		L78-0036-05	RESØNATØR 4.19MHZ	
R1 R2 R3 R4 R5		RK73FB2A563J RK73FB2A1B3J RK73FB2A333J RK73FB2A473J RK73FB2A472J	CHIP R 56K J 1/10W CHIP R 18K J 1/10W CHIP R 33K J 1/10W CHIP R 47K J 1/10W CHIP R 4.7K J 1/10W	
R6 ,7 R8 R9 R10 R11 -15		RK73FB2A473J RK73FB2A331J RK73FB2A562J RK73FB2A103J RK73FB2A473J	CHIPR 47K J 1/10W CHIPR 330 J 1/10W CHIPR 5.6K J 1/10W CHIPR 10K J 1/10W CHIPR 47K J 1/10W	

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参照看号	位置新		部品名/規格	nation marks 仕 向 備考
R16 R17 R18 R21 R22		RK73FB2A184J RK73FB2A390J R92-0670-05 R92-0670-05 R92-0670-05	CHIP R 180K J 1/10W CHIP R 39 J 1/10W CHIP R 0 0HM CHIP R 0 0HM CHIP R 0 0HM	E AT E
R23 R25 R26 R27 +28 R32		R92-0670-05 R92-0670-05 R92-0670-05 R92-0670-05 RK73FB2A102J	CHIPR O NHM CHIPR 1.0K J 1/10W	E(W)
R33 R34 R35 R37		RK73FB2A101J RK73FB2A100J R92-0670-05 RK73FB2A123J	CHIP R 100 J 1/10W CHIP R 10 J 1/10W CHIP R 0 NHM CHIP R 12K J 1/10W	E
S1 -3 S4 S5		\$40-1415-05 \$31-1420-05 \$31-2414-05	PUSH SWITCH (M®NI,LAMP,PTT) SLIDE SWITCH (F.L®CK) SLIDE SWITCH (L®/HI)	
115 D1 +2 D3 +4 D5 D6 +7	2A	FTD8608 1S3184 1SS181 SLH34VC3 LN01301C(Q)	LCD DINDE DINDE LED (TX) LED	
IC1 IC2 IC3 Q1 Q2		LH5008TP 75108AG-028-22 S8054ALR 2SC2712(Y) 2SA1162(Y)	IC(LCD CONTROLLER/ DRIVER) IC(MICROPROCESSOR) IC(RESET IC) TRANSISTOR TRANSISTOR	
119	2B	W02-0400-05	ENCODER	
	TX-		X) -11 : TH-55AT -61 : TH-55E	<del> </del>
C1 -5 C6 C7 CB C9		CC73FSL1H101J C92-0004-05 C90-1408-05 C90-2053-05 CK73FB1H471K	CHIP C 100PF J CHIP TAN 1UF 16WV ELECTRN 220UF 6.3WV ELECTRN 47UF 6.3WV CHIP C 470PF K	
C10 C11 C12 C13 C14		CC73FCH1H1R5C CK73FB1E103K CK73FB1H471K CC73FSL1H101J C90-2053-05	CHIP C 1.5PF C CHIP C 0.010UF K CHIP C 470PF K CHIP C 100PF J ELECTRO 47UF 6.3WV	
C15 C16 C18 -20 C21 C22		CC73FSL1H101J CC73FCH1H02OC CC73FSL1H101J CK73FB1H471K CK73FB1E103K	CHIP C 100PF J CHIP C 2.0PF C CHIP C 100PF J CHIP C 470PF K CHIP C 0.010UF K	
C23 C24 C25 -27 C28 C29		CC73FCH1H020C CK73FB1E103K CC73FSL1H101J CC73FCH1H040C CK73FB1H471K	CHIP C 2. OPF C CHIP C 0.010UF K CHIP C 100PF J CHIP C 4. OPF C CHIP C 470PF K	
C30 C31 C32 C33 C34		CK73FB1E103K CK73EB1E104K CK73FB1E103K CC73FSL1H101J C90-2041-05	CHIP C 0.010UF K CHIP C 0.10UF K CHIP C 0.010UF K CHIP C 100PF J ELECTRO 10UF 10WV	

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and M: Other Areas

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Ref. No.	Address		Parts No.	Description	Re-
参照番号		arts 新	部品番号	部品名/規格	marks 備考
C35 C36 C37 C38 C39			CC73FSL1H101J CK73FB1E103K CK73EB1E104K C90-2039-05 CC73FSL1H101J	CHIP C 100PF J CHIP C 0.010UF K CHIP C 0.10UF K ELECTRO 15UF 16WV CHIP C 100PF J	
C40 C41 C42 C43 -45 C46			CK73FB1E103K CK73EB1E104K C90-2041-05 CC73FSL1H101J CC73FCH1H010C	CHIP C 0.010UF K CHIP C 0.10UF K ELECTRO 10UF 10WV CHIP C 100PF J CHIP C 1.0PF C	
C47 ,48 C49 C50 ,51 C52 C53			CC73FSL1H101J CK73FB1H102K CC73FCH1H04OC CC73FCH1H07OD CK73FB1H471K	CHIP C 100PF J CHIP C 1000PF K CHIP C 4.0PF C CHIP C 7.0PF D CHIP C 470PF K	
C54 C55 C56 C57 ,58 C59			CC73FSL1H101J CC73FCH1H01OC CK73FB1E103K CC73FSL1H101J CC73GCH1H04OC	CHIP C 100PF J CHIP C 1.0PF C CHIP C 0.010UF K CHIP C 100PF J CHIP C 4.0PF C	
C60 C61 C62 C63 +64 C65			CC73FSL1H101J CC73FCH1H1R5C CK73FB1E103K CC73FSL1H101J CC73FCH1H0R5C	CHIP C 100PF J CHIP C 1.5PF C CHIP C 0.010UF K CHIP C 100PF J CHIP C 0.5PF C	
C66 C67 C68 C69 C70			CC45FCH1H12OJ CK73FB1E1O3K CC73FCH1H0BOD CK73FB1E1O3K CC73FCH1H05OC	CERAMIC 12PF J CHIP C 0.010UF K CHIP C 8.0PF D CHIP C 0.010UF K CHIP C 5.0PF C	
071 072 073 074 075			CK73FB1E103K C90-2050-05 CK73FB1E273K C90-2053-05 C90-2052-05	CHIP C 0.010UF K ELECTR® 33UF 6.3WV CHIP C 0.027UF K ELECTR® 47UF 6.3WV ELECTR® 68UF 10WV	
C77 -79 C80 C81 C82 C83			CC73FSL1H101J CC73FCH1H1R5C CC73FCH1H020C CC73FCH1H1R5C CC73FSL1H101J	CHIP C 100PF J CHIP C 1.5PF C CHIP C 2.0PF C CHIP C 1.5PF C CHIP C 100PF J	
A3 CN1 CN2 CN3 W1		*	E40-5128-05 E40-5164-05 E40-5127-05	GND TERMINAL (P.MODULE) FPC CONNECTOR (20P) PIN CONNECTOR (8P) PIN CONNECTOR (7P) CONNECTING WIRE(11P-AVR)	
W2 W3		*		CONNECTING WIRE(5P-AF,SQ) CONNECTING WIRE(CTCSS)	
A2 A4 A6 A7	28	* * *	F11-1101-04 F20-0594-04	SHIELDING COVER(P. MODULE) SHIELDING COVER(LPF) INSULATING SHEET(FPC-CTCSS) SHIELDING PLATE(DRIVER)	
A1	2B	*		MOUNTING HARDWARE(P.MODULE)	
L1			L92-0123-05	BEAD CORE	

E: Scandinavia & Europe K: USA

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⚠ indicates safety critical components.

× New Parts

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Ref. No.	Address	New Parts	Parts No.	De	scription			Re-
参照者号	位置	新	部品番号	部品	名/規	格	nation 仕 向	marks 備考
L2 L3 L4 L5 L6			L92-0122-05 L40-1021-14 L92-0123-05 L92-0122-05 L40-1021-14	BEAD CORE SMALL FIXED BEAD CORE BEAD CORE SMALL FIXED				
L7 ,8 L9 L11 L12 L13		* * * *	L92-0124-05 L33-0710-05 L34-1230-05 L79-0830-05 L79-0829-05	FERRITE CHIP CHOKE COIL COIL FILTER FILTER	(HELIC			
L14 L15 L16 ,17 L18 X1		*	L34-4090-05 L40-3372-80 L92-0123-05 L92-0122-05 - L77-1379-05	COIL SMALL FIXED BEAD CORE BEAD CORE CRYSTAL RESO				
XF1 ,2			L71-0280-05	MCF	59.7MHZ			
Р	2B	*	NO9-2034-05	SCREW	(M2.6X5)			
CP1 JP1 +3 R1 R2 R3		*	R90-0706-05 R92-1061-05 RK73FB2A680J RK73FB2A474J RK73FB2A473J	MULTI-COMP JUMPER REST CHIP R CHIP R CHIP R	10KX5 0 9HM 68 470K 47K	J 1/10W J 1/10W J 1/10W		
R5 R6 R7 RB R9			RK73FB2A393J RK73FB2A103J RK73FB2A473J RK73FB2AB22J RK73FB2A391J	CHIP R CHIP R CHIP R CHIP R CHIP R	39K 10K 47K 8. 2K 390	J 1/10W J 1/10W J 1/10W J 1/10W J 1/10W		
R10 R11 R12 R13 R14			RK73FB2A331J RK73FB2A100J RK73FB2A331J RK73FB2A102J RK73FB2A470J	CHIP R CHIP R CHIP R CHIP R CHIP R	330 10 330 1.0K 47	J 1/10W J 1/10W J 1/10W J 1/10W J 1/10W		i
R15 R16 R17 R18 R19			RK73FB2A100J RK73FB2A471J RK73FB2A390J RK73FB2A220J RK73FB2A102J	CHIP R CHIP R CHIP R CHIP R CHIP R	10 470 39 22 1. OK	J 1/10W J 1/10W J 1/10W J 1/10W J 1/10W		
R20 R21 ,22 R23 R25 R26	-		RK73FB2A103J RK73FB2A101J RK73FB2A272J RK73FB2A103J RK73FB2A471J	CHIP R CHIP R CHIP R CHIP R CHIP R	10K 100 2.7K 10K 470	J 1/10W J 1/10W J 1/10W J 1/10W J 1/10W		
R27 R28 R29 R30 R31	:		RK73FB2A150J RK73FB2A120J RK73FB2A153J RK73FB2A150J RK73FB2A6B1J	CHIP R CHIP R CHIP R CHIP R CHIP R	15 12 15K 15 680	J 1/10W J 1/10W J 1/10W J 1/10W J 1/10W		
R32 R33 R34 R35 R36			RD14BB2CB22J RK73FB2A334J RK73FB2A103J RK73FB2A222J RK73FB2A331J	RD CHIP R CHIP R CHIP R CHIP R	8. 2K 330K 10K 2. 2K 330	J 1/6W J 1/10W J 1/10W J 1/10W J 1/10W		
R37			RK73FB2A334J	CHIP R	330K	J 1/10W		

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参照者号	位置新		部品名/規格	仕 向 備考
R38 R39 R40 R41 R42		RK73FB2A222J RK73FB2A104J RK73FB2A105J RK73FB2A222J RK73FB2A153J	CHIP R 2.2K J 1/10W CHIP R 100K J 1/10W CHIP R 1.0M J 1/10W CHIP R 2.2K J 1/10W CHIP R 15K J 1/10W	
R50 +51 R52 R53 R54 VR1	2A	R92-0670-05 RK73FB2A332J RK73FB2A392J RK73FB2A472J R23-9403-05	CHIP R O 8HM CHIP R 3.3K J 1/10W CHIP R 3.9K J 1/10W CHIP R 4.7K J 1/10W POTENTIOMETER1OK/5OK(AF,SQ)	
D1 ,2 D3 D4 D5 D6		* -MA77 DA204K HSM88AS MA110 * MA77	CHIP DIBDE CHIP DIBDE CHIP DIBDE CHIP DIBDE CHIP DIBDE CHIP DIBDE	
IC1 IC2 Q1 Q2 ,3 Q5		* _M57787 * MD-004 * DTA114YU 2SC4093(R27) 2SC4093(R27)	IC(P0WER M0DULE/ 1.24-1.3GHZ) IC(ANTENNA C0NTROL) DIGITAL TRANSISTOR CHIP TRANSISTOR CHIP TRANSISTOR	
06 ,7 08 09 010		* -2SC4095(R47.6) * -2SC3585(R44.3) 2SC2714(0) * 2SJ144(GR)	CHIP TRANSISTOR CHIP TRANSISTOR CHIP TRANSISTOR CHIP FET	
127 128 129 129 130		* \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	IF UNIT PLL,VC0 UNIT MIC AMP UNIT MIC AMP UNIT AF UNIT	AT E
131 132	1 1	* -X59-3420-00 * -X59-3430-00	APC UNIT	
	· <del></del>	IF UNIT	(X58-3210-01)	
C1 C2 C3 C4 C5 -8		CK73EB1E104K C92-0004-05 C92-0005-05 CK73FB1E223K CK73FB1H102K	CHIP C 0.10UF K CHIP TAN 1UF 16WV CHIP-TAN 2.2UF 6.3WV CHIP C 0.022UF K CHIP C 1000PF K	
010 011 013 014 015		CK73FB1H102K C92-0001-05 C92-0005-05 CC73FCH1H150J CC73FCH1H220J	CHIP C 1000PF K CHIP TAN 0.1UF 35WV CHIP-TAN 2.2UF 6.3WV CHIP C 15PF J CHIP C 22PF J	
C16 C17 -19 C20 C21		CK73FB1E103K CK73EB1E104K CC73FCH1H820J CK73FB1E103K	CHIP C 0.010UF K CHIP C 0.10UF K CHIP C 82PF J CHIP C 0.010UF K	
•		E23-0610-05	TERMINAL	
CD1 CF1 L1		L79-0817-05 L72-0362-05 L40-3982-81	CERAMIC DISCRIMNATER(CDBM455C7 CERAMIC FILTER (CFUM455E) SMALL FIXED INDUCTOR(0.39UH)	
R1 R2 R3		RK73FB2A152J RK73FB2A332J RK73FB2A102J	CHIP R 1.5K J 1/10W CHIP R 3.3K J 1/10W CHIP R 1.0K J 1/10W	

E: Scandinavia & Europe K: USA

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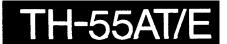
U: PX(Far East, Hawaii) T: England

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参照者号	位置	Parts 新	部品番号	部品名	/規格	nation mark 仕 向備考
R4 R5 R6 R7 R8			RK73FB2A274J RK73FB2A473J RK73FB2A102J RK73FB2A332J RK73FB2A472J	CHIP R 270 CHIP R 47k CHIP R 1.0 CHIP R 3.3 CHIP R 4.3	J 1/10W DK J 1/10W BK J 1/10W	
R9 R10 R11 R12 R14			RK73FB2A561J RK73FB2A103J RK73FB2A122J RK73FB2A222J RK73FB2A681J	CHIP R 560 CHIP R 100 CHIP R 1.2 CHIP R 2.2 CHIP R 680	C J 1/10W 2K J 1/10W 2K J 1/10W	
R15 TH1 VR1		*	RK73FB2A101J R92-0680-05 R12-5425-05	CHIP R 100 FIXED RESISTOR( TRIMMING POT.(15	. 5K)	
Dt IC1 Q1		*	HSM88AS -TK10486MT1(B,C) 2SC2712(GR)	CHIP DINDE IC(FM IF) CHIP TRANSISTNR		
			PLL UNIT	(X58-3360-00)		
C1 C2 C3 C4 C5		*	CK73GB1E103K CK73GB1H471K CC73GCH1H060D CK73GB1H102K CC73GCH1H180J	CHIP C 470	JOPF K	
C6 C7 C8 C9 ,10 C11			CC73GCH1H12DJ CC73GCH1H47DJ CC73GCH1H56DJ CK73GB1E1D3K CC73GCH1H22DJ	CHIP C 126 CHIP C 476 CHIP C 566 CHIP C 0.0 CHIP C 226	PF J PF J 310UF K	
C12 C13 C14 C15 C16		*	CK73GB1H471K C92-0509-05 CK73GB1E103K CK73FB1E333K CK73GB1H222K	CHIP C 0.0		
C17 C18 C19 C20 C24			CK73GB1E103K C92-0509-05 CC73FSL1H101J C92-0003-05 C92-0504-05	TANTAL 10L CHIP C 10C CHIP TAN 0.4	010UF K UF 6.3WV OPF J 17UF 25WV 68UF 20WV	
C25 TC1		*	C92-0502-05 C05-0361-05	ELECTRO 0.3 TRIMMING CAP 200	33UF 35WV PF	
			E23-0603-05	TERMINAL		
A1 A2		*	F11-1102-03 F11-1103-04	SHIELDING CASE SHIELDING COVER		
L1 X1		*	L40-2272-80 <del>-</del> L77-1378-05	SMALL FIXED INDI CRYSTAL RESONATO		
JP1 -3 R1 R2 R3 R4			R92-1061-05 RK73GB1J471J RK73GB1J151J RK73GB1J153J RK73GB1J102J	JUMPER REST D (CHIP R 470 CHIP R 150 CHIP R 150 CHIP R 1.0	J 1/16W C J 1/16W	
R5 R6 R7			RK73GB1J473J RK73GB1J333J RK73GB1J153J	CHIPR 471 CHIPR 333 CHIPR 151	< J 1/16₩	

E: Scandinavia & Europe K: USA

P: Canada W:Europe

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★ indicates safety critical components.

# TH-55AT/E

# **PARTS LIST**

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Ref. No.	Address Ne		Description	Desti- Re-
参照番号	位 筐 新		部品名/規格	nation marks 仕 向 備考
R8 R9 R10 R11 R12 +13	k	RK73GB1J103J RK73GB1J223J RK73GB1J102J RK73GB1J101J RK73GB1J222J	CHIP R 10K J 1/16W CHIP R 22K J 1/16W CHIP R 1.0K J 1/16W CHIP R 100 J 1/16W CHIP R 2.2K J 1/16W	
R14 R15 R16 R17 R18	k	RK73GB1J103J RK73GB1J101J RK73GB1J472J RK73GB1J394J RK73GB1J103J	CHIP R 10K J 1/16W CHIP R 100 J 1/16W CHIP R 4.7K J 1/16W CHIP R 390K J 1/16W CHIP R 10K J 1/16W	74 E
R19 ,20 R21 R22		RD14BB2C103J RK73GB1J222J RK73GB1J472J	RD 10K J 1/6W CHIP R 2.2K J 1/16W CHIP R 4.7K J 1/16W	
D1 IC1 IC2 Q1 Q2	k   ;   k		CHIP DIBDE IC(PRE SCALER) IC(PLL FRED SYNTHESIZER) CHIP TRANSISTBR DIGITAL TRANSISTBR	
03 04 05 TH1	1.	2SJ144(GR) 2SC3624(L18) 2SC2712(GR) 159-153-85013	CHIP FET CHIP TRANSISTOR CHIP TRANSISTOR THERMISTER 15K	
	<u> </u>	X59-3470-00	VCS UNIT	
	MIC /	<del></del>	XX) -11 : TH-55AT -61 : TH-55E	<del></del>
C1 C2 C3 ,4 C5 ,6 C7		C92-0002-05 CK73FB1E223K CC73FSL1H101J C92-0005-05 CK73FB1E103K	CHIP TAN 0.22UF 35WV CHIP C 0.022UF K CHIP C 100PF J CHIP-TAN 2.2UF 6.3WV CHIP C 0.010UF K	
08 09 010 011 012 +13		CC73FSL1H151J CK73FB1H182K C92-0507-05 CK73FB1E103K CK73FB1E473M	CHIP C 150PF J CHIP C 1800PF K CHIP TAN 4.7UF 6.3WV CHIP C 0.010UF K CHIP C 0.047UF M	E
C13 C14		CK73FB1E103K CK73FB1E103K	CHIP C 0.010UF K CHIP C 0.010UF K	AT
		E23-0610-05	TERMINAL	
R1 R1 R2 R3 R4		RK73FB2A104J RK73FB2A334J RK73FB2A272J RK73FB2A103J RK73FB2A472J	CHIP R 100K J 1/10W CHIP R 330K J 1/10W CHIP R 2.7K J 1/10W CHIP R 10K J 1/10W CHIP R 4.7K J 1/10W	AT E
R5 R6 R6 R7 R8		RK73FB2A391J RK73FB2A154J RK73FB2AB23J RK73FB2A472J RK73FB2A100J	CHIP R 390 J 1/10W CHIP R 150K J 1/10W CHIP R 82K J 1/10W CHIP R 4.7K J 1/10W CHIP R 10 J 1/10W	E
R9 R10 R11 ,12 R13 R14		RK73FB2A273J RK73FB2A223J RK73FB2A104J RK73FB2A472J RK73FB2A104J	CHIP R 27K J 1/10W CHIP R 22K J 1/10W CHIP R 100K J 1/10W CHIP R 4.7K J 1/10W CHIP R 100K J 1/10W	

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学無者号 R15 R16 R17 VR1 IC1 TH1	位 置	Parts 新	## ## ## ## ## ## ## ## ## ## ## ## ##	CHIP R CHIP R CHIP R	名/規 150 33K	格 J 1/10W	nation	Re- marks 備考
R16 R17 VR1 IC1 TH1 C1 C2 C3 C5			RK73FB2A333J RK73FB2A473J R12-1439-05	CHIP R CHIP R		T 1/10U		
C1 C2 C3 C5				TRIMMING POT	47K	J 1/10W J 1/10W	Ε	
C2 C3 C5			NJM4560M 159-101-83052	IC(OP AMP X2 THERMISTER	100			
C2 C3 C5			AF AMP UN	IT (X58-3380-00	)			
1			CC73FSL1H221J CK73FB1E393K CK73FB1E223K CK73FB1E223K CK73FB1E473M	CHIP C CHIP C CHIP C CHIP C CHIP C	220PF 0. 039UF 0. 022UF 0. 022UF 0. 047UF	Ј К К К		
C7 C8 C9 C10 C11			C92-0005-05 CC73FSL1H101J C92-0501-05 CC73FSL1H101J CK73FB1E473M	CHIP TAN CHIP C CHIP TAN CHIP C CHIP C	2. 2UF 100PF 1. 5UF 100PF 0. 047UF	M 6' 3MA 7 6' 3MA		
C12 C13 C14 C15			CC73FSL1H101J C90-2053-05 CK73FB1H102K C92-0004-05	CHIP C CHIP TAN CHIP C CHIP TAN	100PF 47UF 1000PF 1UF	J 6.3WV K 16WV		
		·	E23-0610-05	TERMINAL				
R1 R2 R3 R4 R5			RK73FB2A102J RK73FB2A334J RK73FB2A392J RK73FB2A154J RK73FB2A152J	CHIP R CHIP R CHIP R CHIP R CHIP R	1. OK 33OK 3. 9K 15OK 1. 5K	J 1/10W J 1/10W J 1/10W J 1/10W J 1/10W		
R6 R7 R8 R9 R10	-		RK73FB2A472J RK73FB2A153J RK73FB2A471J RK73FB2A273J RK73FB2A100J	CHIP R CHIP R CHIP R CHIP R CHIP R	4. 7K 15K 470 27K 10	J 1/10W J 1/10W J 1/10W J 1/10W J 1/10W		
R1 1			RK73FB2A103J	CHIP R	10K	J 1/10W		
D1 IC1 Q1 Q2 Q3		*	02CZ6.8X ~NJM386BM 2SB1182F5(Q) 2SC4081(BR) DTC144EU	CHIP ZENER D IC(0P AMP) CHIP TRANSIS CHIP TRANSIS DIGITAL TRANS	T®R T®R∙	-		
Q4		*	2SC4081(BR)	CHIP TRANSIS	TOR			
	<del></del>	<del>,</del>		(X59-3420-00)		· · · · · · · · · · · · · · · · · · ·		
C1 -13 C14 C15 C16 C17 -21			CC73FSL1H101J CK73FB1E223K CC73FSL1H101J C92-0005-05 CC73FSL1H101J	CHIP C CHIP C CHIP C CHIP TAN CHIP C	100PF 0. 022UF 100PF 2. 2UF 100PF	J 6.3WV 1		
			E23-0610-05	TERMINAL				
R1 R2 R3 R4 R5			RK73FB2A152J RK73FB2A182J RK73FB2A561J RK73FB2A153J RK73FB2A332J	CHIP R CHIP R CHIP R CHIP R CHIP R	1.5K 1.8K 560 15K 3.3K	J 1/10W J 1/10W J 1/10W J 1/10W J 1/10W	:	3

E: Scandinavia & Europe K: USA

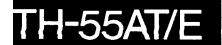
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参照番号	位置	Perts ≸f	部品番号	部品名/規格		marks 備考
R6 R7 R8 R9 VR1		*	RK73FB2A102J RK73FB2A272J RK73FB2AB22J RK73FB2A123J R12-3463-05	CHIP R 1.0K J 1/10W CHIP R 2.7K J 1/10W CHIP R 8.2K J 1/10W CHIP R 12K J 1/10W TRIMMING POT. (22K)HI		
VR2	: :	*	R12-1441-05	TRIMMING POT. (1K)LOW		
D1 D2 Q1 Q2 Q3		*	DA204U MA110 2SB1182F5(Q) IMX1 FMW1	CHIP DIØDE CHIP DIØDE CHIP TRANSISTØR DIGITAL TRANSISTØR DIGITAL TRANSISTØR		- <del>1</del> .
Ω4			2SB1182F5(Q)	CHIP TRANSISTOR		
				(X59-3430-00)		
C1 C2 C3 C4 C5 ,6			CC73FCH1H030C CC73FCH1HR75C CC73FCH1H040C CC73FCH1H020C CC73FCH1H030C	CHIP C 3. OPF C CHIP C 0. 75PF C CHIP C 4. OPF C CHIP C 2. OPF C CHIP C 3. OPF C		•
C7 C8 ,9 C1O C11 ,12	2		CC73FCH1H22OJ CC73FCH1H03OC CC73FCH1H08OD CC73FCH1H04OC	CHIP C 22PF J CHIP C 3. OPF C CHIP C 8. OPF D CHIP C 4. OPF C		
			E23-0610-05	TERMINAL		
0.1				(X59-3470-00)	T	
C1 C2 C3 C4 C5	,	·	CK73FB1E103K CC73GSL1H101J CC73GCH1H040C CC73GCH1H02OC C92-0509-05	CHIP C 0.010UF K CHIP C 100PF J CHIP C 4.0PF C CHIP C 2.0PF C TANTAL 10UF 6.3WV		
C6 C7 C8 C9 C10			CC73GSL1H101J CC73FCH1HOR5C CC73FCH1H04OC CC73GCH1H04OC CC73GCH1H0R5C	CHIP C 100PF J CHIP C 0.5PF C CHIP C 4.0PF C CHIP C 4.0PF C CHIP C 0.5PF C		
C11 +12 C13 C14 C15 C16			CC73GCH1H03OC CC73GCH1H02OC CK73GB1H1O2K CC73GSL1H1O1J CK73GB1H471K	CHIP C 3. OPF C CHIP C 2. OPF C CHIP C 1000PF K CHIP C 100PF J CHIP C 470PF K		
C17 C18 C19 C20 C21			CK73EB1E104K CC73GSL1H101J CK73FB1E103K CC73GSL1H101J CK73GB1H102K	CHIP C 0.10UF K CHIP C 100PF K CHIP C 0.010UF K CHIP C 100PF K CHIP C 1000PF K		
TC1 TC2			C05-0357-05 C05-0345-05	CERAMIC TRIMMER (3PF) CERAMIC TRIMMER (10PF)		
L1 L2 L3 L4			L40-1072-80 L40-1092-81 L40-1081-80 L40-4792-81	SMALL FXED INDUCTOR(10NH) SMALL FXED INDUCTOR(1UF) SMALL FXED INDUCTOR(100NH) SMALL FXED INDUCTOR(4.7UF)		·
R1 R2			RK73GB1J123J RK73GB1J100J	CHIP R 12K J 1/16W CHIP R 10 J 1/16W		

E: Scandinavia & Europe K: USA

P: Canada W:Europe

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U: PX(Far East, Hawaii) T: England UE: AAFES(Europe)

X: Australia

M: Other Areas

\* New Parts

Parts without Parts No. are not supplied.

Les articles non mentionnes dans le Parts No. ne sont pas fournis.

Telle ohne Parts No. werden nicht geliefert.

Ref. No.	Addres		Parts No.	Description	Desti- Re-	
参照者号	位值	Parts 扩新	部品書号	部品名/規	格	nation mar 仕 向 備 <sup>3</sup>
R3 R4 R5 R6 R7			RK73GB1J101J RK73GB1J470J RK73GB1J100J RK73GB1J682J RK73GB1J101J	CHIP R 100 CHIP R 47 CHIP R 10 CHIP R 6.8K CHIP R 100	J 1/16W J 1/16W J 1/16W J 1/16W J 1/16W	
R9 R10			RK73GB1J391J RK73GB1J562J	CHIP R 390 CHIP R 5.6K	J 1/16W J 1/16W	
01 02 ,3 01 02 03 ,4		*	MA77 MA360 25K508(K51) 2SC4093(R26,27) DTC114YU	CHIP DIØDE CHIP DIØDE CHIP FET CHIP TRANSISTØR DIGITAL TRANSISTØR		
88			RK73GB1J104J	CHIP R 100K	J 1/16W	
; · · · · · · · · · · · · · · · · · · ·						

E: Scandinavia & Europe K: USA

P: Canada W:Europe

U: PX(Far East, Hawaii) T: England

M: Other Areas

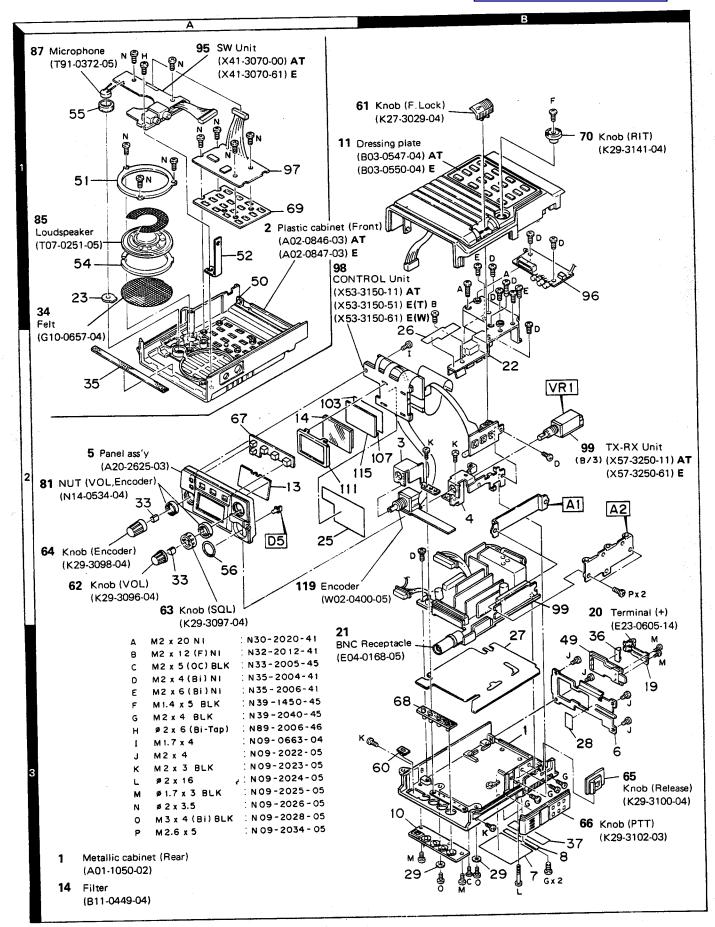
UE: AAFES(Europe)



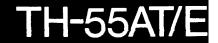
# **DISASSEMBLY**

Downloaded by ☐
Amateur Radio Directory ☐

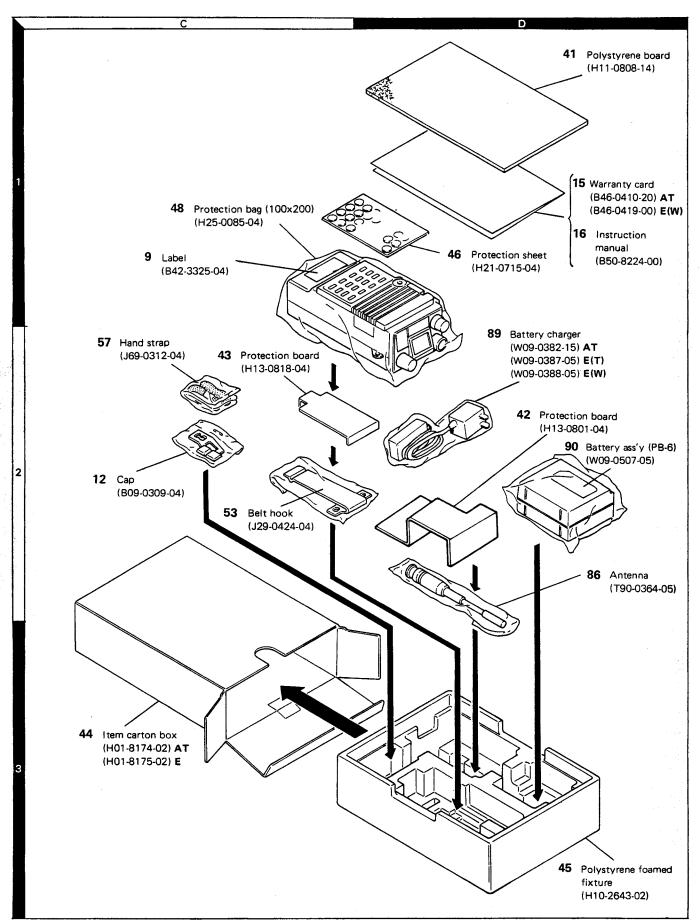
www.hamdirectory.info

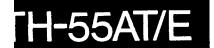


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# **PACKING**





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#### REQUIRED TEST EQUIPMENT

#### 1. Stabilized Power Supply

- 1) The supply voltage can be changed between 5V and 18V, and the current is 3A or more.
- 2) The standard voltage is 9.0V.

### 2. DC Ammeter

- 1) Class 1 ammeter (17 ranges and other features).
- 2) The full scale can be set to either 300mA or 1A.
- 3) A cable of less internal loss must be used.

## 3. Frequency Counter (f. counter)

- 1) Frequencies of up to 1300MHz or so can be measured.
- 2) The sensitivity can be changed to 250MHz or below, and measurements are highly stable and accurate (0.2ppm or so).

#### 4. Power Meter

- 1) Measurable frequency: 1300MHz or more.
- 2) Impedance :  $50\Omega$ , unbalanced.
- 3) Measuring range: Full scal of 10W or so.
- 4) A standard cable (5D2W 1m) must be used.

#### 5. Linear Detector

- 1) Measurable frequency: Up to 1300MHz.
- 2) Characteristics are flat, and CN is 60dB or more.

#### 6. Digital Voltmeter

- 1) Voltage range : FS = 18V or so.
- 2) Input resistance :  $1M\Omega$  or more.

#### 7. Oscilloscope

- 1) Measuring range: DC to 30MHz.
- 2) Provides highly accurate measurments for 5 to 25MHz.

### 8. AF Voltmeter (AF VTVM)

- 1) Measurable frequency: 50Hz to 1MHz.
- 2) Maximum sensitivity: 1mV or more.

### 9. Spectrum Analyzer

1) Measuring range: DC to 1300MHz or more.

### 10. Standard Signal Generator (SSG)

- 1) Maximum frequency: 1300MHz or more.
- 2) Output:  $-20dB/0.1\mu V$  to 120dB/1V.
- 3) Output impedance :  $50\Omega$ .

#### 11. Tracking Generator

- 1) Center frequency: 50kHz to 1500MHz.
- 2) Frequency deviation: ±35MHz.
- 3) Output voltage: 100mV or more.

#### 12. Dummy Load

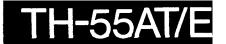
1)  $8\Omega$ , 3W or more.

#### **PREPARATION**

 Set the unit in the receiving mode and set the controls as follows, unless otherwise specified.

POWER/VOL		٠			•					•	. ON
SQL VR											MIN
F. LOCK											OFF
HI/I OW											. HI

- Use a non-conductive rod such as a Bakelite rod for adjustment (especially of trimmers and coils).
- To protect the SSG, do not send out signals while adjusting the receiving unit.
- The indicated SSG output levels are for maximum output.



### TX-RX COMMON ADJUSTMENT

		Mea	sureme	nt		Ad	justment		
item	Condition	Test- equipment	Unit	Terminal	Unit	Parts	Method	Specifications/Remarks	
1. Reset	1) Hold dowm M key POWER SW : ON							Dispaly 1260.000	
2. DC voltage	1) DC power : 9V	DC V.M					Check	9V	
check	2) 5C	-				·		5V	
	3) 5R	, jag							
	4) 5M			MA A					
	5) 5T PTT : ON						. # # The state of		

### PLL ADJUSTMENT

		Me	nt		Ad	ljustment	~		
item	Condition	Test- equipment	Unit	Terminal	Unit	Parts	Method	Specifications/Remarks	
1. VCV	1) FREQ. : 1299.975MHz	DC V.M	MIC AMP	TP1	vco	TC1	3.7V	±0.2V	
	2) PTT : ON	Power				TC2	3.7∨	±0.2V	
	3) FREQ. : 1258.000MHz	meter					Check	1.5V ± 0.3V	
2. Reference frequency	1) FREQ.: 1280.100MHz HI/LOW SW: LOW RIT: Center PTT: ON	f. counter Power meter		ANT	SW	VR1	1280.100MHz	± 100Hz	
	2) FREQ.: 1280.100MHz RIT: Center SSG output: -98dBm/2.82µV	SSG AF V.M Oscillo- scope Distortion meter		EXT.SP	PLL	TC1	SINAD MAX.		

### **RX ADJUSTMENT**

		Me	nt		Ad	justment			
ltem	Condition	Test- equipment	Unit	Terminal	Unit	Parts	Method	Specifications/Remarks	
1. Helical	1) Tracking generator output : - 40dBm	T.G.		ANT	TX-RX	L12, L13	•	MAX. gain and bandwidth	
	2) Spectrum analyzer reference level : —40dBm RF ATT : 10dB	Spectrum analyzer	TX-RX	TP2			REF  -40/8m  5d8m/dIV  Tracking generator  OUT: -38d8m  Spectrum analyzer  CENTER I  FREO. SPAN  100MH1  REF  -40d8m  5d8m/dIV	CENTER. f. FRED. SPAN 100MHz	
2. IF	1) FREQ.: 1285.000MHz Adjust the output level of SSG to flicker the 3rd segment of S-meter.	SSG S-meter		S-meter	TX-RX	L14	Turn the L14 to the point at which 3rd segment of S-meter appear.		
3. Sensitivity	1) FREQ.: 1280.100MHz SSG output: —107dBm/1µV	Oscillo- scope AF V.M		EXT.SP				SINAD 12dB or more.	
	2) FREQ. : 1258.100MHz SSG output : 104dBm/1.41µV	Distortion meter							
	3) FREQ.: 1299.900MHz SSG output: 107dBm/1μV								
4. S-meter	1) FREQ.: 1285.000MHz SSG output: -93dBm/5µV	SSG		S-meter	IF	VR1	Adjust the VR1 to all segments light on.		
	2) SSG output : 103dBm/1.58μV						Check	All segments light off.	

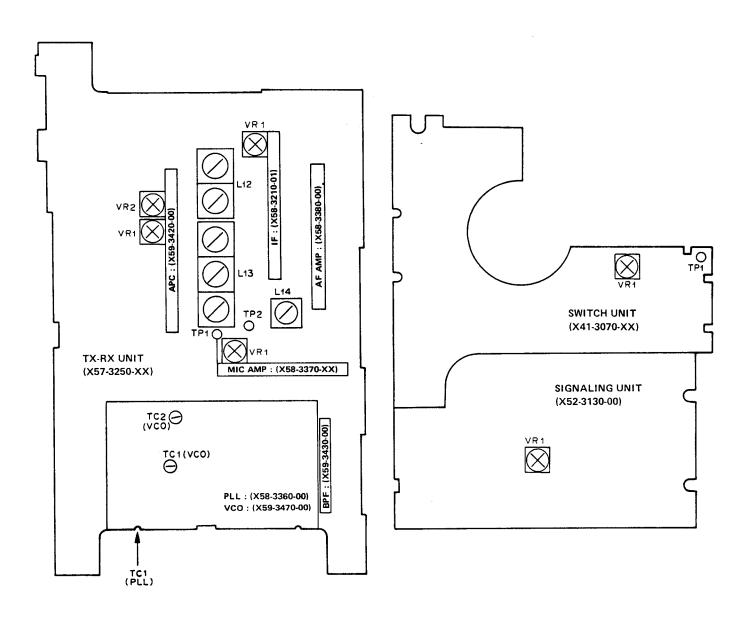


## **FX ADJUSTMENT**

	:	Mea	suremer	nt		Ad	justment	1	
item	Condition	Test- equipment	Unit	Terminal	Unit	Parts	Method	Specifications/Remarks	
1. Output power	1) DC power 9V FREQ.: 1258.000MHz HI/LOW SW: LOW PTT: ON	Power meter		ANT	APC	VR1	100mW	± 20mW Power consumption : 600mA or less.	
	2) HI/LOW SW : HI					VR2	1.1W	Power consumption : 1A or less.	
	Repeat 2 or 3 times to adjusting VR1 and VR2.				1 - \$12-1			# 1 A	
2. DEV	1) FREQ.: 1280.000MHz AG: 1kHz, 80mV <b>TH-55AT</b> AG: 1kHz, 40mV <b>TH-55E</b>	Power meter AG		ANT	MIC AMP	VR1	±4.2kHz	$\pm 200$ Hz (CTCSS terminal is terminated with 33k $\Omega$ .)	
	2) AG: 1kHz, 8mV TH-55AT AG: 1kHz, 4mV TH-55E	Linear detector f. counter					Check	±2.3 ~ 3.7kHz	
		E		MIC 10µ 16	ÂĞ	GND	OUT 10µ 18V		
			<u> </u>	100		1/01	DEV . + 2kHz	±200Hz	
7. DTMF TH-55AT only	1) FREQ.: 1280.000MHz Push A and B key.			ANT	Signal- ing	VR1	DEV : ±3kHz f : 1633Hz	+20Hz,10Hz	

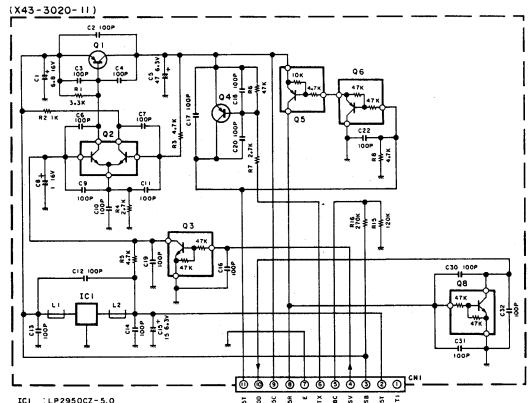


## **ADJUSTMENT POINTS**



# TH-55AT/E PC BOARD VIEWS/CIRCUIT DIAGRAM

AVR UNIT (X43-3020-11)



ICI : LP2950CZ-5.0

Q١ :2581182F5(Q)

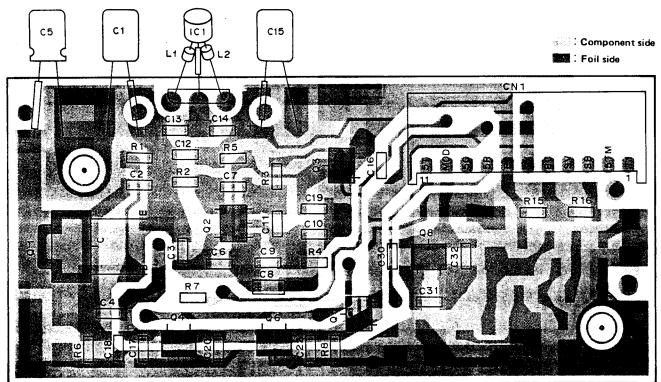
: FMW I

Q3,8 : DTC144EK

Q4 :2SA1313(Y) Q5 : DTA143 XK

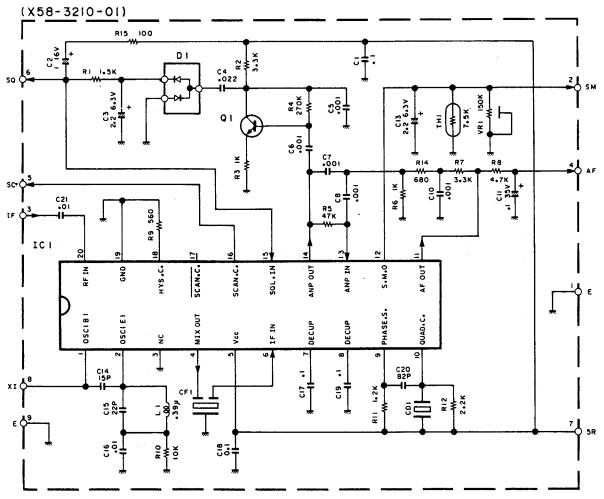
Q6 : DTAI44EK

## Component side view



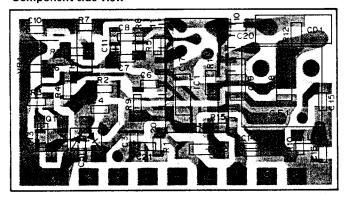
# PC BOARD VIEWS/CIRCUIT DIAGRAM TH-55AT/E

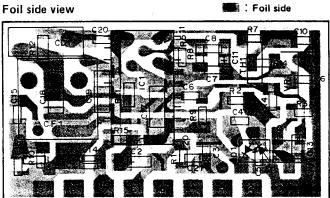
IF UNIT (X58-3210-01)



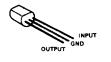
ICI : TK10486M(B,C), : 2SC2712 (GR) QI : HSM88AS

### Component side view





LP2950CZ-5.0



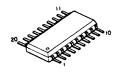
FMW1



2SA1313(Y) 2SC2712(GR) DTA143XK DTA144EK DTC144EK

2SB1182F5(Q)

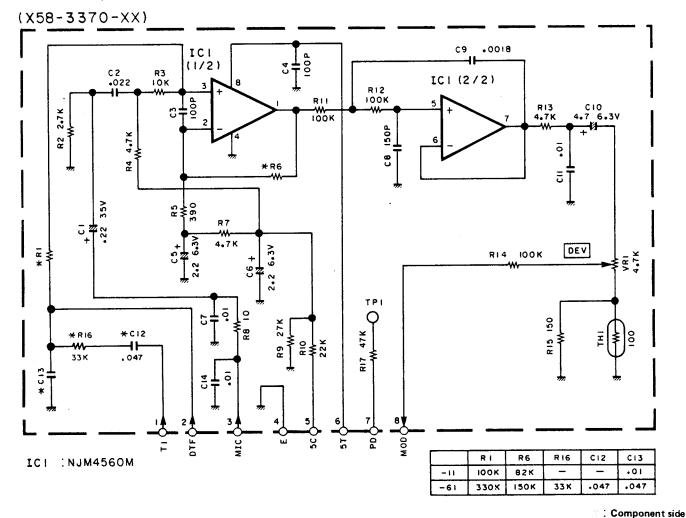
TK10486MT1(B,C)



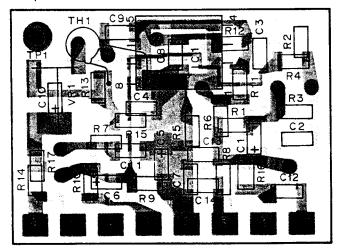
: Component side

### TH-55AT/E PC BOARD VIEWS/CIRCUIT DIAGRAM

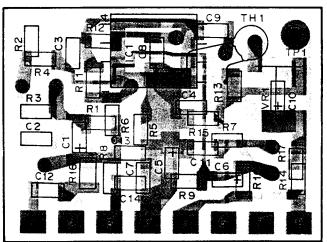
MIC AMP UNIT (X58-3370-XX) -11: TH-55AT -61: TH-55E



### Component side view



Foil side view



: Foil side

DTC144EU 2SC4081(BR)



2SB1182F5(Q)

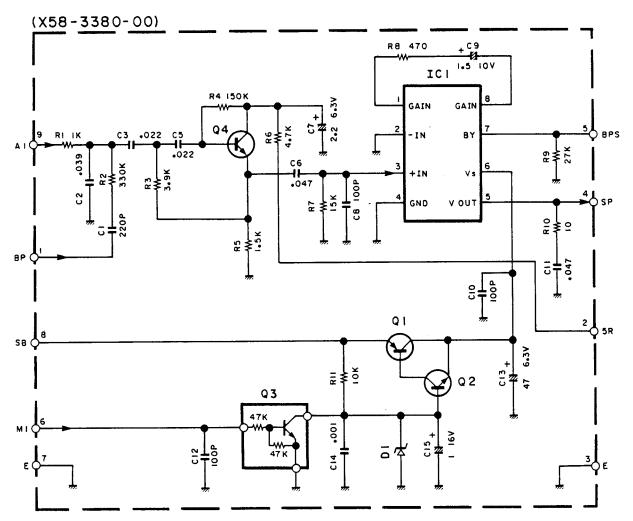


NJM386BM NJM4560M



# PC BOARD VIEWS/CIRCUIT DIAGRAM TH-55AT/E

AF AMP UNIT (X58-3380-00)



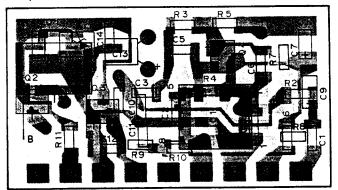
:NJM386BM ICi

:2SB1182F5(Q) Q2,4:2SC4081(BR)

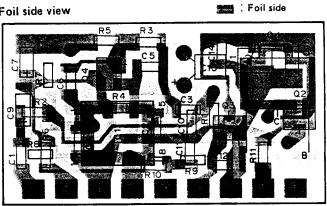
Q3 : DTC144EU

: 02CZ 6.8X or RD 6.8 M-BI

### Component side view



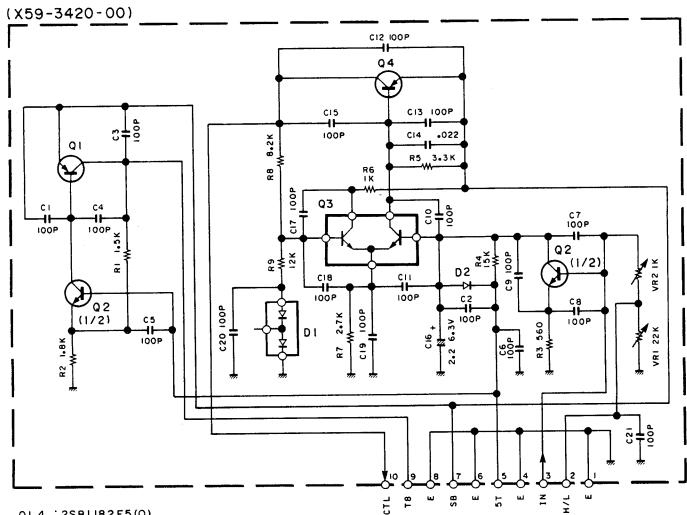
### Foil side view



: Component side

## TH-55AT/E PC BOARD VIEWS/CIRCUIT DIAGRAM

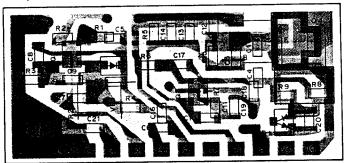
APC UNIT (X59-3420-00)



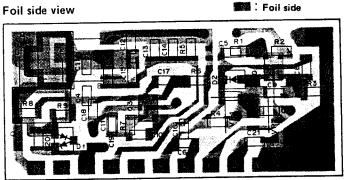
Q1,4 :2581182F5(Q)

Q2 IMMXI : FMWI Q3 DI : DA204U D2 : MAIIIO

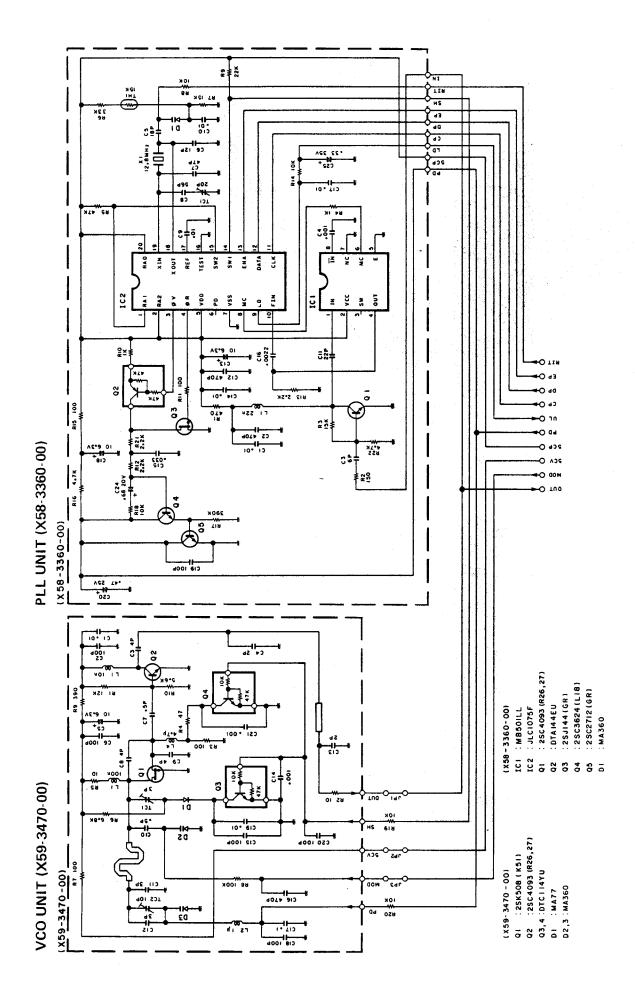
#### Component side view







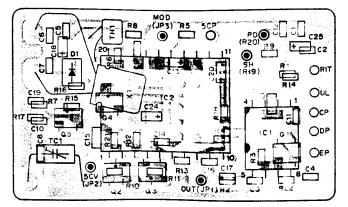
: Component side



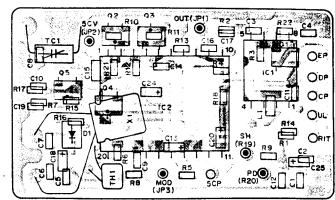
## PC BOARD VIEWS/CIRCUIT DIAGRAM TH-55AT/E

PLL UNIT (X58-3360-00)

Component side view



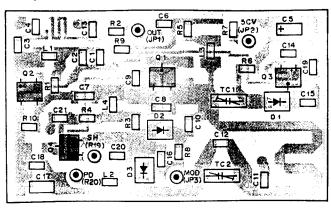
Foil side view

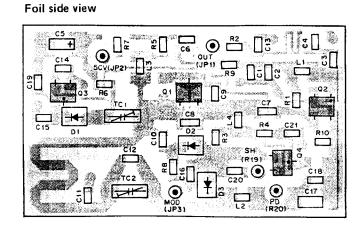


Component side
Foil side

VCO UNIT (X59-3470-00)

Component side view





2SC4093(R26, 27)

2SC2712(GR)

2SC3624(L18)

DTA144EU

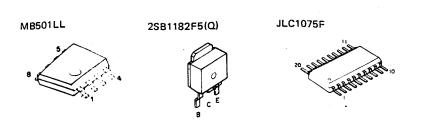
DTC114YU

B

S

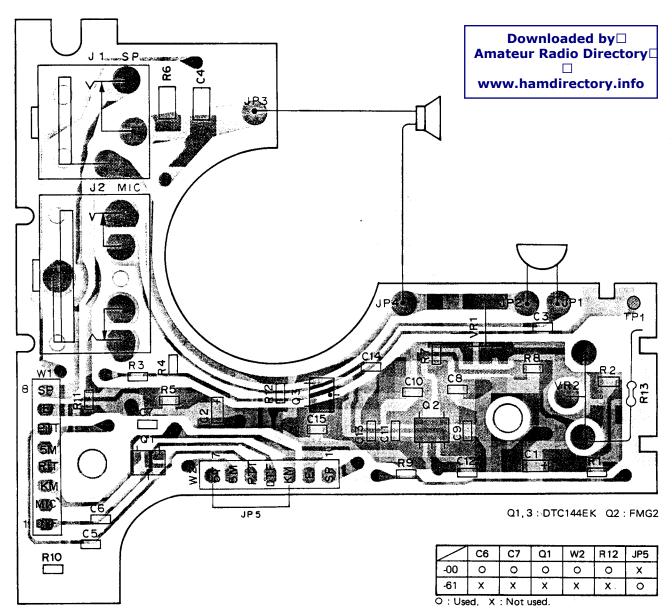
DTC114YU

B

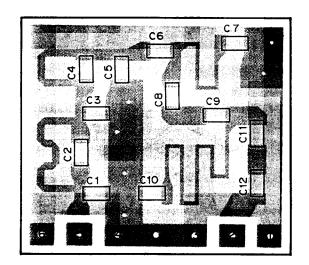


# TH-55AT/E PC BOARD VIEWS

SWITCH UNIT (X41-3070-XX) -00 : TH-55AT -61 : TH-55E Component side view

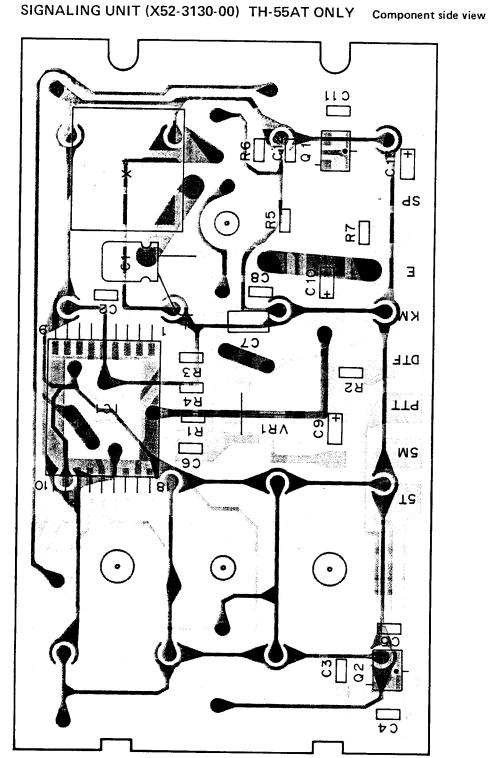


BPF UNIT (X59-3430-00) Component side view



: Component side

Foil side

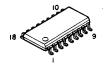


2SA1162(Y) 2SC2712(GR) 2SC2712(Y) DTA114EK DTC144EK

FMG2



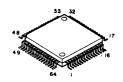
LR40872



LH5008TP



75108AG-028-22

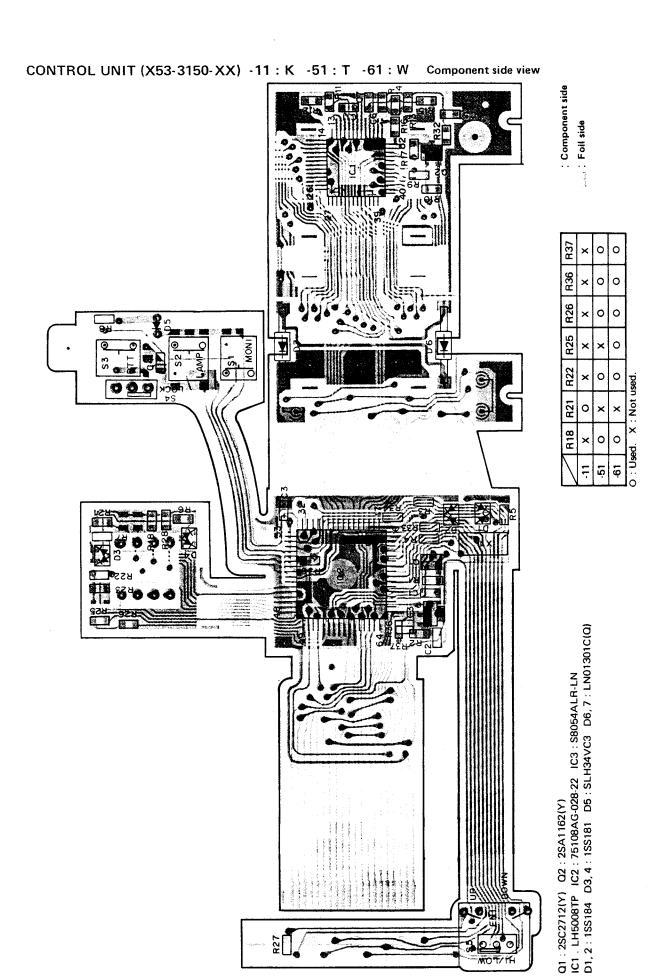


S8054ALR-LN

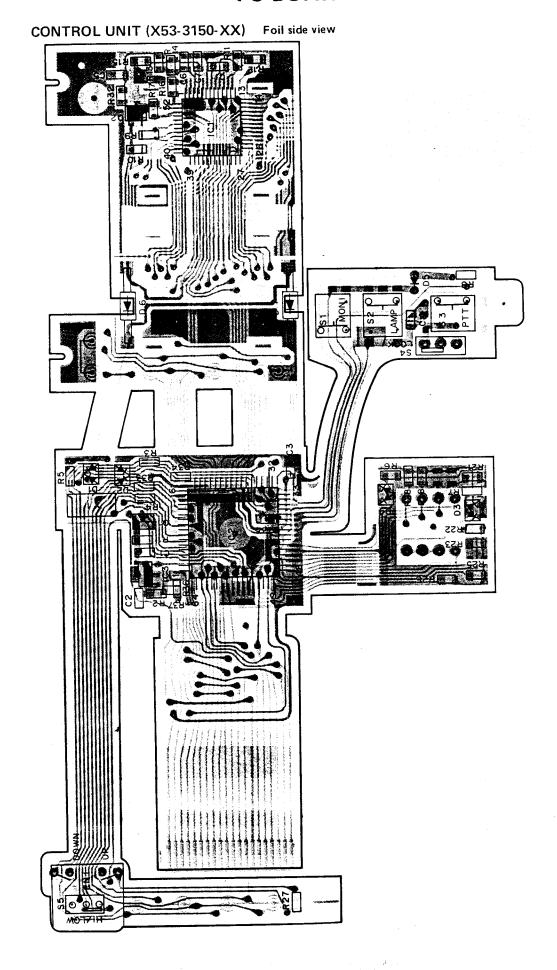


Q1: 2SC2712(GR) Q2: DTA114EK

IC1: LR40872



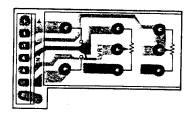
# PC BOARD VIEWS TH-55AT/E

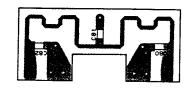


# TH-55AT/E PC BOARD VIEWS

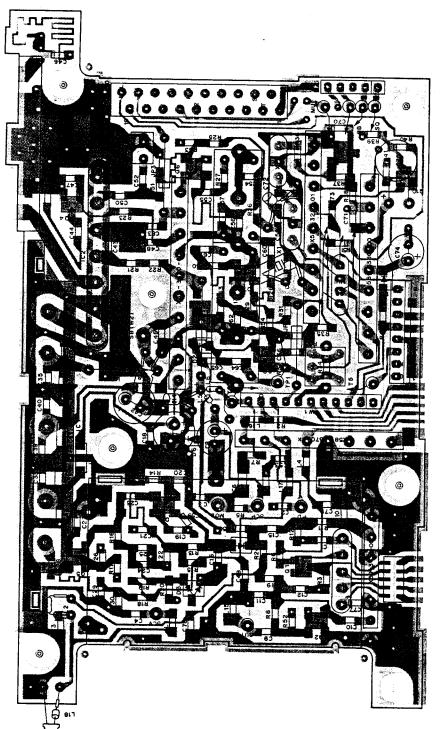
TX-RX UNIT (X57-3250-XX) -11 : TH-55AT -61 : TH-55E Co

Component side view





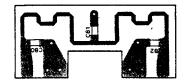
: Component side

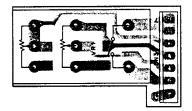


Q1: DTA114YU Q2,3,5: 2SC4093(R27) Q6,7: 2SC4095(R47.6) Q8: 2SC3585(R44.3) Q9: 2SC2714(O) Q10: 2SJ144(GR) IC1: M57787 IC2: MD-004 D1,2,6: MA77 D3: DA204K D4: HSM88AS D5: MA110

47

TX-RX UNIT (X57-3250-XX) Foil side view









MD-004



DTA114YU 2SC3585(R44.3) 2SC2714(O)

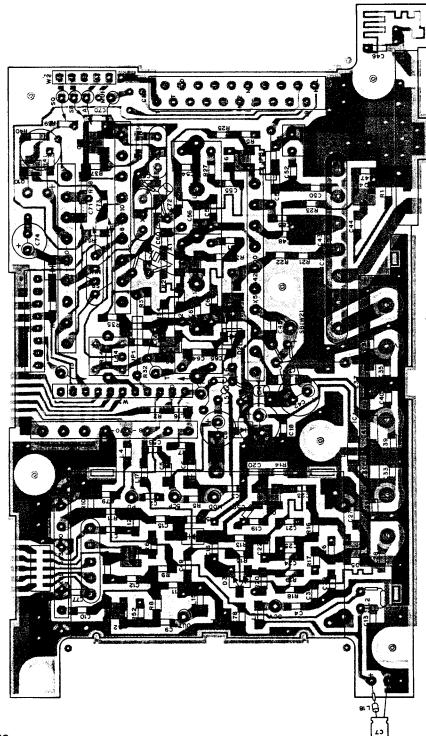


2SC4093(R27) 2SC4095(R47,6)

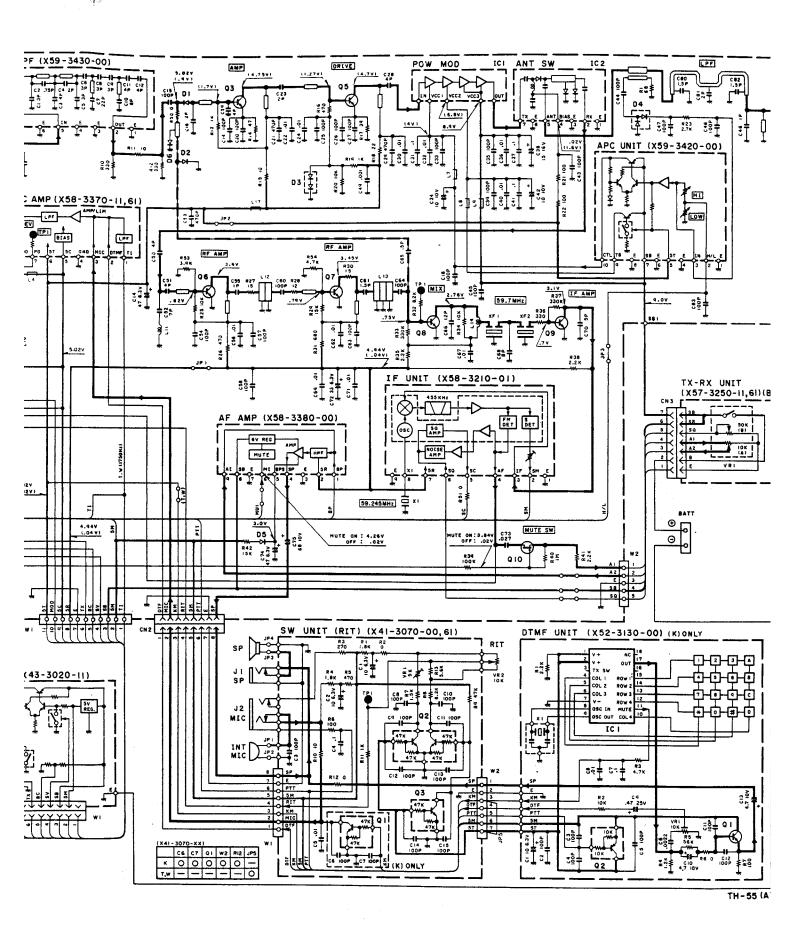


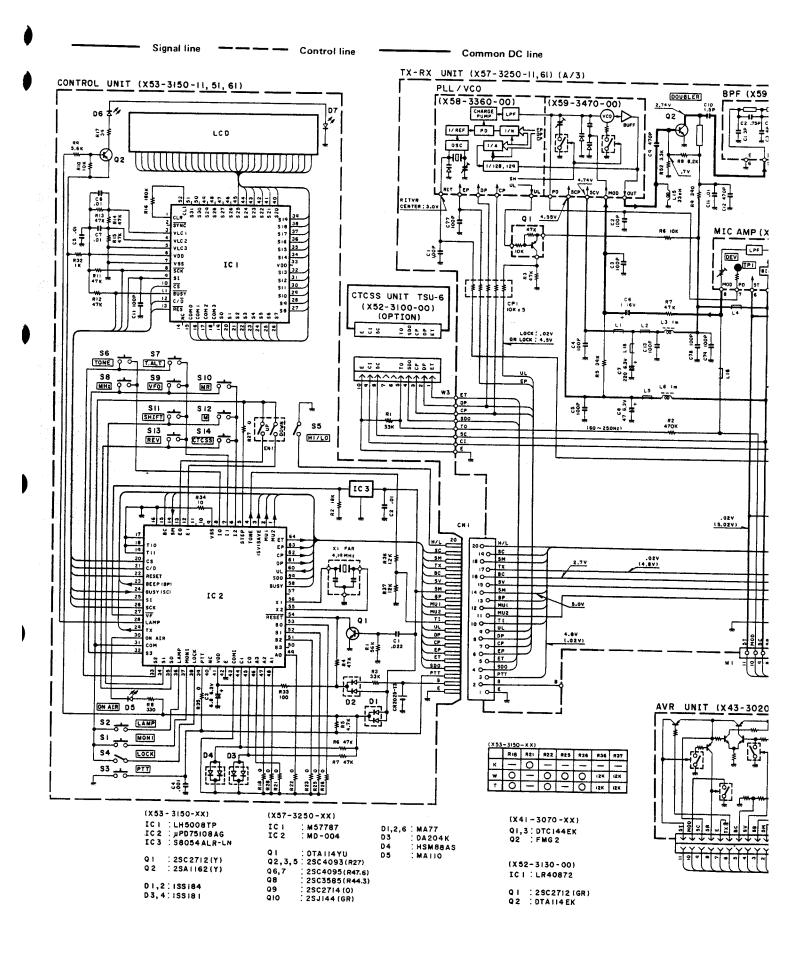
2SJ144(GR)



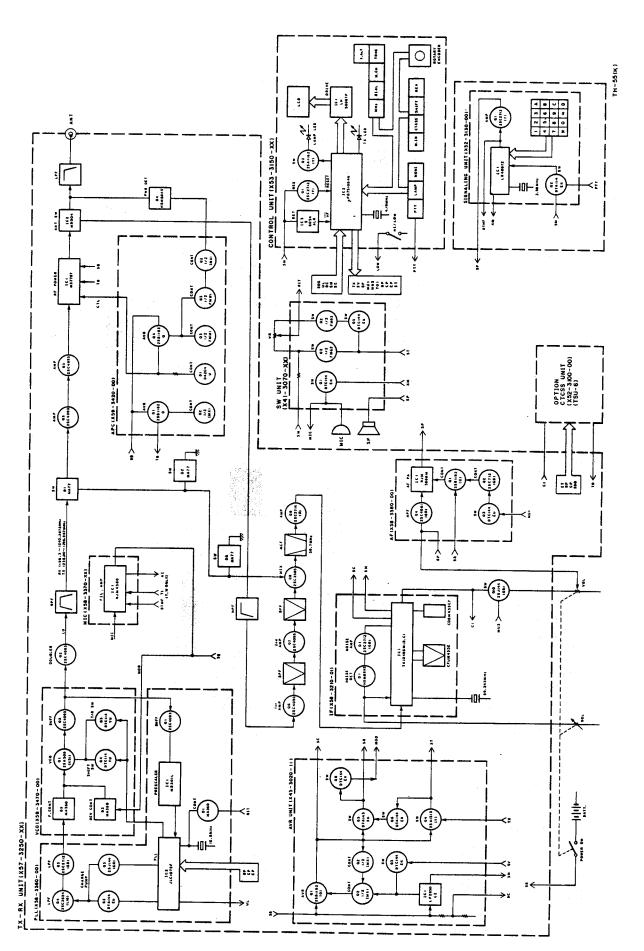


## SCHEMATIC DIAGRAM TH-55AT/



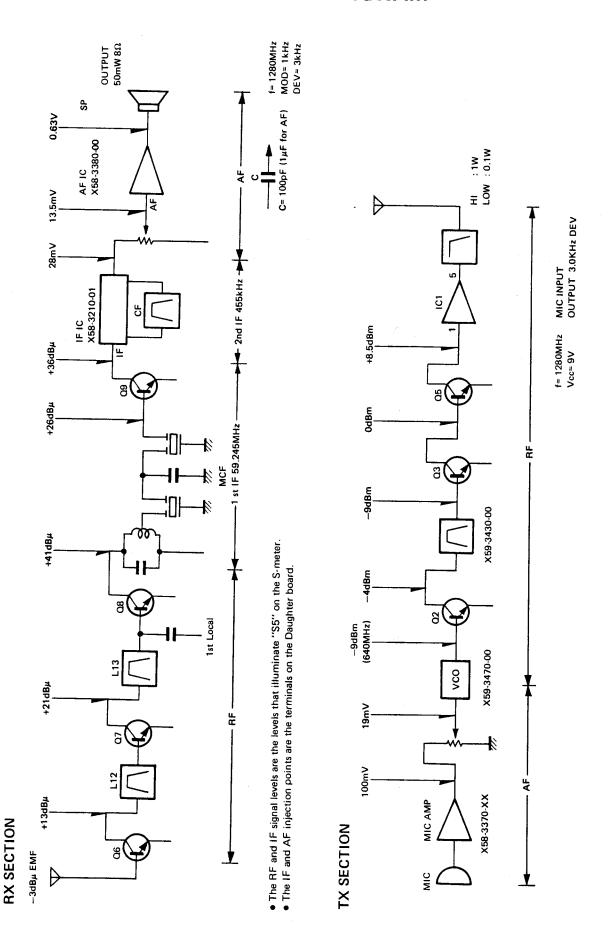


### **BLOCK DIAGRAM**



# TH-55AT/E

### **LEVEL DIAGRAM**

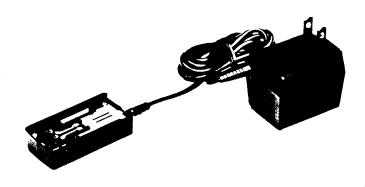




# TERMINAL FUNCTIONS/BC-9 (BATTERY CHARGER)

Connecto No.	r Termina No.	Termina Name	Function
			A/3) CONTROL UNIT
CN1	1	E	Ground.
	2	В	Not used.
l	3	PTT	PTT SW signal. "L" : TX, "H" : RX.
	4	SDO	Tone signal match/mismatch
261			identification signal.
	5	·ET	Tone enable.
	6	EP	PLL enable.
	7	CP	Clock signal.
	8	DP	PLL tone serial data.
1 6	10	UL TI	PLL unlock signal.
	11	MU2	1750Hz tone signal. <b>TH-55E</b> Mute signal. "H": Mute.
Ж,	12	MU1	Mute signal. "H": Mute.
1.50	13	BP	Beep signal.
	14	5M	5V power supply for MUP and MIC.
	15	sv	SAVE signal output.
	1	1	"L" : Save, "H" : Normal.
	16	ВС	Battery voltage check signal.
	17	TX	Transmit/receive switching signal.
	1		"L" : TX, "H" : RX.
	18	SM	S-meter signal.
	19 20	SC	Busy signal
		H/L	High/Low power switching signal.
W3			IIT (A/3) — TSU-6
WS	1 2	ET DT	Tone enable.
	3	СТ	Tone serial data.
	4	SDO	Clock signal.  Tone signal match/mismatch
		000	identification signal.
	5	то	Tone output,
	6	PTT	Not used.
*	7	co	Not used.
	8	5C	5V power supply.
	9	CI	Audio signal input.
	10	E	Ground.
	TX-RX		A/3) — SWITCH UNIT
CN2	1 1	DTMF	DTMF signal. TH-55AT
	2	MIC	Signal line from microphone.
	3	KM	MIC mute signal.
	4	RIT	RIT voltage.
	6	5M PTT	5V power supply for MUP and MIC.
	7	Ε	External standby line. Ground.
	8	SP	Signal line to built in speaker.
	TX-RX II		3) - TX-RX UNIT (B/3)
W2	1	A1	AF volume input line.
	2	A2	AF amplifier input line.
	3	E	Ground.
	4	SB	B power supply after power switch.
	5	SQ	Squelch volume input line.
	TX-R	X UNIT	(A/3) — AVR UNIT
W1	1	TI	Not used.
	2	5M	5V power supply for MPU and MIC.
	3	SB	B power supply after power switch.
:	4	sv	Battery save signal.
	5	вс	Battery voltage check signal.
	6	TX	Transmit signal.
1	7	E	Ground.
	8	5C	Common 5V power supply.
	9	5R MOD	5V power supply for receive.
-	10	MOD	Not used.
	' !	5T	5V power supply for transmit.

### **BC-9 EXTERNAL VIEW**



### **BC-9 PARTS LIST**

Ref. No.	New Parts	Parts No.	* : New Part
		A02-0814-03	Case (Charge adapter)
73.7		A40-0622-04	Bottom plate
		B42-3301-04	Label (LA) (K)
		E23-0494-04	Terminal (-)
		E23-0605-04	Terminal +
# <sup>*</sup>		G13-0852-04	Cushion
		J19-1426-03	Terminal holder

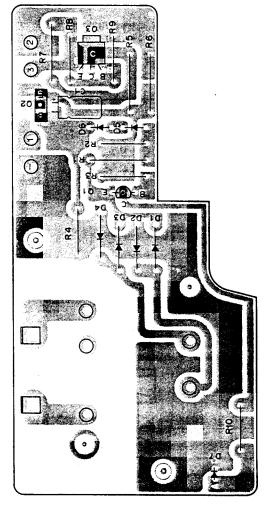
# TH-55AT/E

### **BC-10 (COMPACT CHARGER)**

### **BC-10 EXTERNAL VIEW**



### **BC-10 PC BOARD VIEW**

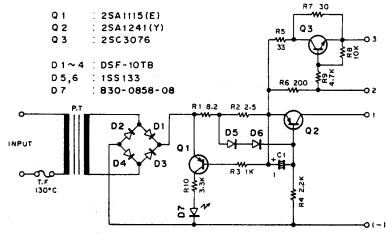


### **BC-10 PARTS LIST**

\* : New Parts

Ref. No.	New	Parts No.	Description
	Parts		·
	*	A02-0828-08	Case (Upper) K,M,M2
		A02-0829-08	Case (Upper) X,T,W
,, 5		A02-0832-08	Case (Lower)
D7	•	B30-0858-08	LED SR615D
	٠	B50-8203-08	Instruction manual
			K,M,M2,X,W
	•	850-8204-08	Instruction manual T
		E30-2097-08	AC power cord K,M,M2
		E30-2098-08	AC power cord X
- 21	•	E30-2099-08	AC power cord T
	•	E30-2100-08	AC power cord W
	•	L01-8027-08	Power transformer 220V M,W
		L01-8111-08	Power transformer 120V K,M2
		L01-8152-08	Power transformer 240V X,T
	•	W02-0805-08	Module
Q1		2SA1115(E)	Transistor
Q2		2SA1241(Y)	Transistor
<b>Q3</b>	•	2SC3076	Transistor
D1-4		DSF-10TB	Diode
D5, 6	<u></u>	1SS133	Diode

### **BC-10 CIRCUIT DIAGRAM**



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#### **BC-11 EXTERNAL VIEW**



#### **BC-11 CIRCUIT DESCRIPTION**

#### General

The BC-11 is a rapid charger for the PB-5 to PB-9 Ni-Cd batteries for TH-25, TH-45 and TH-55.

#### Theory of Operation

The operation of each block is explained below.

#### 1) + 11V AVR Circuit

This AVR circuit, consisting of a 2SD600F transistor (Q1) and DZA11Y Zener diode (DZ1) provides an output of approximately + 11V as the reference voltage for the charging circuit consisting of IC2 to IC5.

### 2) Battery Pack Detect Circuit

This circuit detects whether a battery pack is inserted in the charger. Outputs from this circuit are routed to the reset circuit and the battery recognition circuit.

When a PB-6 or PB-9 is inserted in the charger, a small amount of current flows from Q2: 2SA608E through R9 to the charging terminal B1 and Q2 turns on. As a result, an output of approximately 11V appears at (A) in Figure 1. Similarly when a PB-5 or PB-7 is inserted Q3: 2SA608E turns on and approximately 11V is provided at output (B). When a PB-8 is inserted Q4: 2SA608E turns on and approximately 11V is provided at output (C).

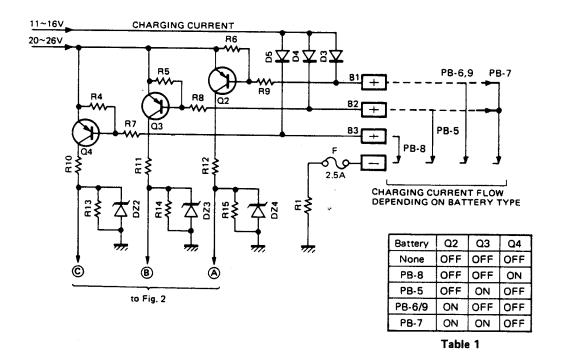


Fig. 1 Battery Pack Detect Circuit Block Diagram



### Reset Circuit/Charge Status Memory Circuit/ Display Circuit

The reset circuit initializes the charging status memory circuit.

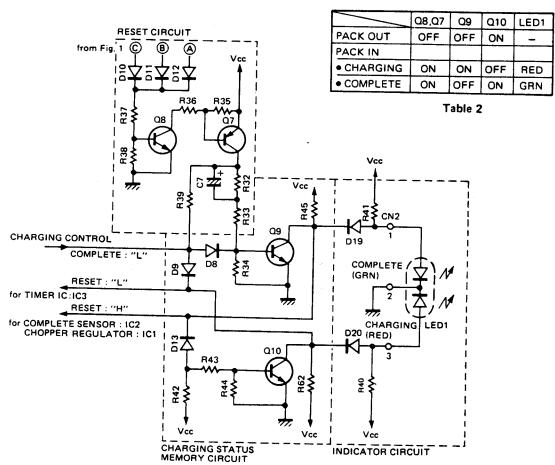


Fig. 2 Reset Circuit/Charge Status Memory Circuit/Display Circuit Block Diagram

The charge status memory circuit is an R-S flip-flop configured from transistors and resistors. The two states of the flip-flop are called COMPLETE and CHARGING. Outputs from the flip-flop drive the LED in the indicator circuit and reset the timer, complete sensor, and chopper regulator. In the COMPLETE state Q9: 2SC536E is off and Q10: 2SC536E is on. In the CHARGING state Q9 is on and Q10 is off.

When a battery pack is not inserted, Q8: 2SC536E and Q7: 2SC536E turn off. As there is no base voltage to Q9, Q9 also turns off. The base of Q10 receives enough bias from Vcc to turn on, resulting in OV at the collector. The current flow through R41 to the COMPLETE indicator in LED1 which glows green, because of Q9 if off.

When the battery pack is inserted Q8 and Q7 turn on. As soon as Q7 turns on, charging current flows through R33, R34, and Q9 to C7 and Q9 turns on. The base voltage of Q10, which is connected to Q9 through diode D13, then drops and Q10 turns off. Since Q10 is off, current flows through R40 to the CHARGING indicator in LED1, which glows red to indicate that the battery is charging. When charging of C7 is completed, on-current continues to flow to the base of Q9 through R39 and D8.

When charging is completed the complete sensor (IC2) outputs a Low ("L")signal that ends the flow of current to the base of Q9, turning Q9 off. As a result current flows through R41 to the COMPLETE indicator in LED1, which glows green to indicate that charging is complete.



#### 4) Battery Recognition Circuit

The battery recognition circuit uses NAND logic to recognize the battery type from the outputs from the battery pack detect circuit. Outputs from this circuit are sent to the charging current limiting circuit and sensor level switching circuit.

	INF	PUT	OUTPUT			
	Α	В	D	F	G	
PB-5	L	Н	Н	Н	L	
PB-6	Н	L	Н	L	Н	
PB-7	Н	Н	L	L	Н	
PB-8	L	L	Н	L	L	
PB-9	Н	L	Н	L	Н	

Table 3

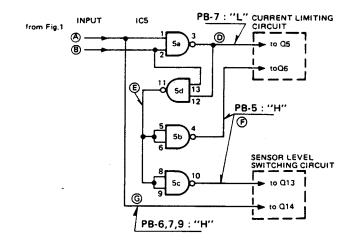


Fig. 3 Battery Recognition Circuit Block Diagram

#### 5) Charging Current Limiting Circuit

This circuit receives the output of the battery recognition circuit and limits the charging current according to the type (current capacity) of battery. The charging current ICR is detected as a voltage drop across R1 (0.15 $\Omega$ ), which is provided to pin 3 of the operational amplifier IC4(1/2): LA6393A. Pin 4 receives a reference voltage (VREF) used as a comparison standard for limiting the charging current. The VREF is changed by ON and OFF of Q5 and Q6 (See **Table 4**).

Pin 2 of IC4: LA6393S provides "L" output when  $V_{\text{REF}} < V_{\text{CR}}$ , stopping the operation of the chopper regulator (IC1.: STK772B) and reducing the charging current. The charging current is limited by the formula:

Icr MAX (A) =  $V_{REF}$  (V)/0.15( $\Omega$ )

	Q5	Q6	VREF	ICR MAX
PB-5	OFF	ON	0.15V	1.0A
PB-6	OFF	OFF	0.25V	1.7A
PB-7	ON	OFF	0.36∨	2.4A
PB-8	OFF	OFF	0.25V	1.7A
PB-9	OFF	OFF	0.25V	1.7A

Table 4

CHOPPER REGULATOR

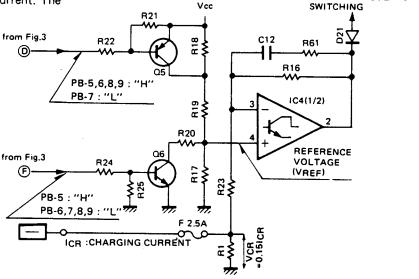
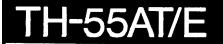


Fig. 4 Charging Current Limiting Circuit Block Diagram



### 6) Sensor Level Switching Circuit

This circuit receives the output of the battery recognition circuit and aligns the voltages supplied to the charging status detect circuit according to the battery type (voltage) so that they are nearly equal at completion of charging.

	SHIFT Es(V)	Q11	Q12
PB-5	2.0	ON	OFF
PB-6	2.0	OFF	ON
P8-7	2.0	OFF	ON
PB-8	7.6	OFF	OFF
PB-9	2.0	OFF	ON

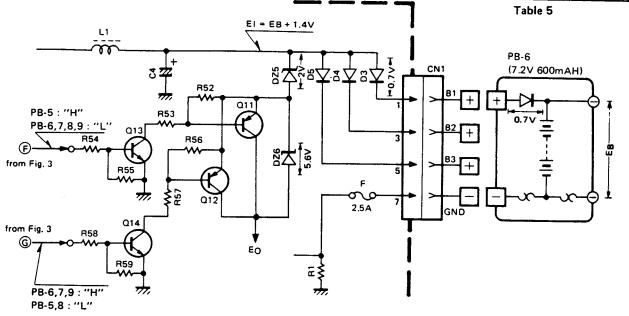


Fig. 5 Sensor Level Switching Circuit Block Diagram

The pin voltages while the Ni-Cd battery is charging are approximately 1.2 times the voltages at the completion of charging. (See **Figure 6**.)

The battery terminal voltage EB is as follows:

Approximately 14.4V for the PB-8

Approximately 8.6V for the PB-5, 6, 7, 9

The charging line voltage EI is the EB voltage plus a 1.4V voltage drop added by a diode.

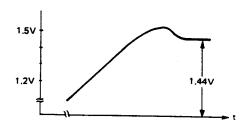


Fig. 6 The pin voltages while the Ni-CD Battery is charging

The EI voltage is output with a level shift as the voltage EO to the charging status detect circuit via Zener diode DZ6 and diodes D17 and D18. The amount of the shift is controlled by switching Q11: 2SA608E and Q12: 2SA608E on and off. (See **Table 5**.) If Eq. (1) is substitued into EO in **Table 5**, the results are:

At the completion of charging the value is approximately 8V.



#### 7) Charging Status Detect Circuit

This circuit detects the completion of charging and outputs a signal to stop charging. When no battery pack is inserted or charging is completed, a High ("H") Reset signal is applied to D15. When a battery is inserted the Reset signal applied to D15 is cleared. When the Reset signal is cleared, pin 4 of IC2: KCH-1003 holds the reset state due to the charge in C8 for the duration of the R46-C8 time constant, then goes "L" to clear the reset state. Pins 8 and 9 of IC2 receive divided portions of the battery voltage.

These inputs are tracked as the charging is performed in the long-term memory capacitor "MD". As the Ni-Cd battery charges, the battery voltage reaches a peak, then declines. (See **Figure 6**.) The MD stores the peak voltage, which is compared with the divided voltages at pins 8 and 9. When the difference  $\Delta V$  is the same, a "L" signal is output fr. "pin 11 to indicate that charging is complete. The signal indicating completion of charging is applied to the charging status memory circuit.

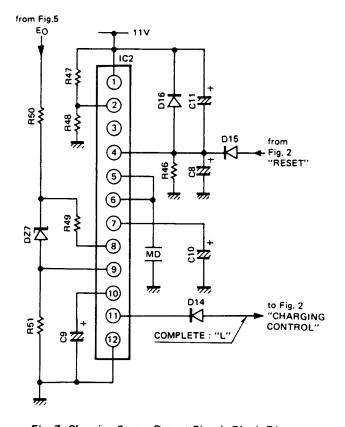


Fig. 7 Charging Status Detect Circuit Block Diagram

#### 8) Timer Circuit

Battery defects may result in charging continuing indefinitely without completion, so this timer outputs a signal that stops charging approximately 1.7 hours after charging begins. When charging begins and the Reset signal is cleared at pin 3, IC3: AN6780 begins counting. At the first count of 16384 pin 6 goes from "H" to "L".

The output from pin 6 is connected to the Stop input (pin 2), so the output of IC3 is held in the "L" state until IC3 receives another Reset signal (for example, when the battery is removed).

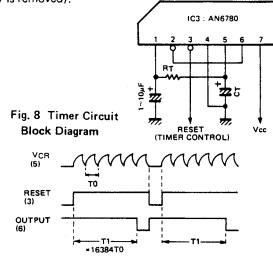


Fig. 9 TIMER TIME T1(s)  $\approx$  11RT(K $\Omega$ )-CT( $\mu$ F) TIMER TIME T1(s)  $\approx$  11x 47(K $\Omega$ )-10( $\mu$ F) = 5170 (s)

### 9) Voltage Comparator Circuit

This circuit monitors the output (EO) of the sensor level switching circuit and indirectly detects abnormal conditions in the battery pack connected to the charging terminal. When the EO voltage falls to 5.2V or lower, the charging control line goes "L" to halt charging.

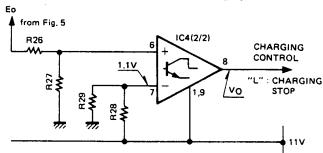
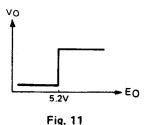


Fig. 10 Voltage Comparator Circuit Block Diagram



# H-55AT/E

#### × New Parts

### **BC-11 (RAPID CHARGER)**

Parts without Parts No. are not supplied.

Les articles non mentionnes dans le Parts No. ne sont pas fournis.

Telle ohne Parts No. werden nicht geliefert.

**BC-11 PARTS LIST** 

	Ref. No.	Address	1 1	Parts No.	Description	Desti-	Re-
	参照者号	位置	Perts #	郑 品 者 号	部 品 名/規 格	1	mark 備考
					BC-11		•
	1	1A	•	A02-0815-08	CASE	1	Γ
	2	1A,1B	•	A02-0817-08	BATTERY POCKET		
	.3	18		B46-0411-00	WARRANTY CARD	K	
	4	18	•	B50-8134-08	INSTRUCTION MANUAL		
1	5	18	•	E23-0604-05	TERMINAL		
۵	6	2A		E30-2038-08	AC CORD	K,M,M2	
۵	6	2A	1 1	E30-2072-08	AC CORD	l w	
۷	6	2A		E30-2073-08	AC CORD	T	
_	6	2A		E30-2095-08	AC CORD	×	
١	8	28		H01-8128-08	ITEM CARTON CASE		
١	9	2B		H10-2584-02	POLYSTYRENE FOAMED FIXTURE (L)		
	10	28		H10-2585-02	POLYSTYRENE FOAMED FIXTURE (R)		
	11	3A		J02-0439-05	FOOT		
	12	3A		J39-0424-05	SPACER		
١	T1	2A		L01-8081-08	POWER TRANSFORMER (AC120V)	K,M2	
4	T1	2A		L01-8112-08	POWER TRANSFORMER (AC220V)	M.W	ŀ
4	T1	2A		L01-8122-08	POWER TRANSFORMER (AC240V)	T,X	
۱	Α	3A		N30-3006-41	MACHINE SCREW (M3 X 6)		
1	В	2A,1B		N34-4006-46	MACHINE SCREW (M4 X 6 TR)		
١	С	2A,1B		N35-4006-45	MACHINE SCREW (M4 X 6 BI) BLK		
I	D	2A		N87-3008-46	TAPTITE SCREW (\$\phi 3 \times 8 BR)		
ĺ	E	1A		N89-3008-45	TAPTITE SCREW (Ø 3 X 8 BI) BLK		
١	SW1	3A		S36-1407-05	POWER SW		
	7	3B	•	W02-0399-08	CHARGE CONTROL UNIT		
				<del></del>			
				CHARGE CONTI	ROL UNIT (W02-0399-08)		
I	C1 C2			CE04EW1V222M	ELECTRO 2200µF 35WV		
1	C2			CE04EW1C470M	ELECTRO 47µF 16WV	]	
J	C3			CE04EW1H010M	ELECTRO 1µF 50WV		
1	C5,6		•	CE04EW1E471M	ELECTRO 470µF 25WV		
	C0,0			CE04EW1C100M	ELECTRO 10µF 16WV		
	C7		.	CE04EW1A101M	ELECTRO 100µF 10WV		
	C8	'		CE04EW1C100M	ELECTRO 10µF 16WV		
1	C9,10			CE04EW0J101M	ELECTRO 100µF 6.3WV		
١	C11			CE04EW1C330M	ELECTRO 33µF 16WV		
	C12			CK45B1H102K	CERAMIC 0.001µF 50WV		
l	C14			CE04EW1H010M	ELECTRO 1µF 50WV		

W:Europe

the state of the s

E: Scandinavia & Europe H:Audio Club K: USA P: Canada

A: Saudi Arabia T: England U: PX(Far East, Hawaii)

<u>UE</u> : AAFES(Europe)

X: Australia M: Other Areas

▲ indicates safety critical components.



× New Parts

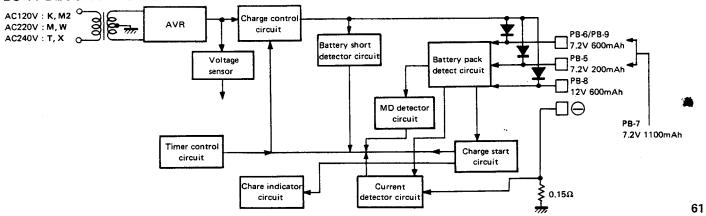
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Les articles non mentionnes dans le Parts No. ne sont pas fournis.

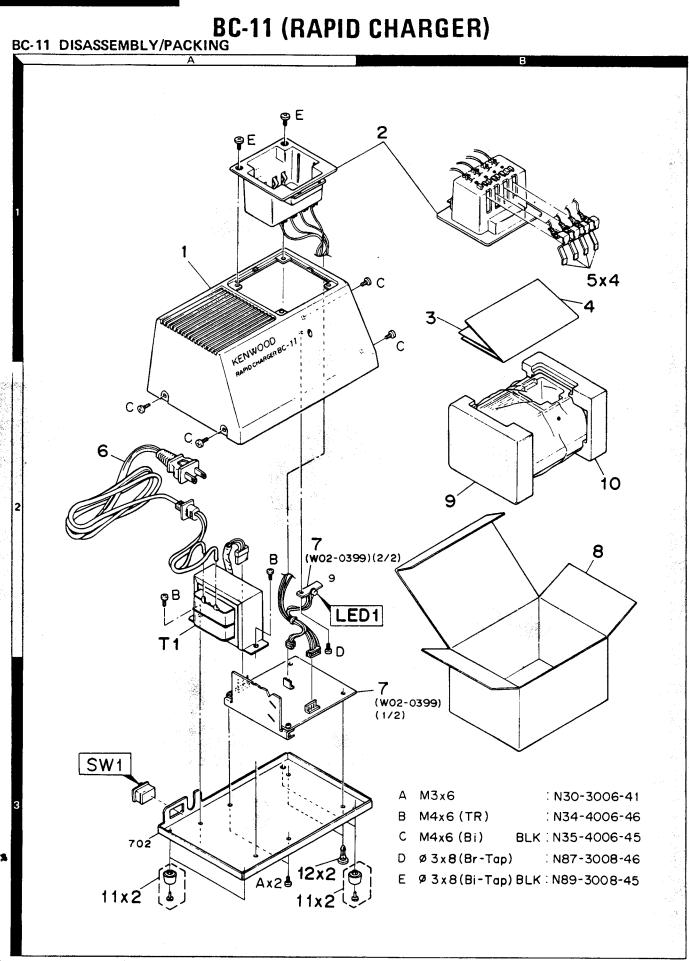
Telle ohne Parts No. werden nicht geliefert.

	Ref.	No.		Add	ress		F	Perts	No.				Des	crip	tion		Des	iti- ion	Re-
	参照	# 4	•	位	世	Perts #	#	A	#	+		#5	*	名 /	/ 規	#	 tt.		48.4
N	ΝD						C91-	038-	08		ELECT	RO							
F	-1						F05-2	2525-	05		FUSE	(2.5A)					w,x		
F	= 1					.	F06-2	2522-	05		FUSE	(2.5A)					M,M	2,T	
F	= 1						F06-2	2523-	05		FUSE	(2.5A)					K		
-	-						J13-0	039-0	05		FUSE	HOLD	ER				w		
l	_1						L33-	0694-	-08		снок	E COI	L (47	/0μH)	)				
F	<del>7</del> 1		-				R92-	0683-	-08		FL-PR	OOF (	).15ເ	2 4W					
(	D1 <b>–</b> 5						DSA:	26B			DIODI	<u> </u>							
Ε	D6—16	3					DS44	12			DIOD	<b>E</b>							
ſ	D19-2	21					DS44	12			DIOD	Ξ.							1
	DZ1						GZA	11Y			ZENE	R DIO	DE (	11V)					
(	DZ2-4	1		]			GZA	10Z			ZENE	R DIO	DE (	10V)					
ŧ	DZ5						GZA	2.0X			ZENE	R DIO	DE (	2V)					
(	DZ6						GZA	5.6X			ZENE	R DIO	DE (	5.6V	)				
(	DZ7						GZA	7.5Y			ZENE	R DIO	DE (	7.5V	)				
(	DZ8						GZA	3.0X			ZENE	R DIO	DE (	3V)					
١	IC1			ŧ			STK	772B			IC (CH					R)			
1	IC2					1	КСН	-1003	3		IC (V	LTA	SE SI	ENSC	R)		1		
ł	C3						AN6	780			IC (TI	-							1
ı	IC4						LA6	3935			IC (D)						1		1
i	IC5						LC40	011B			IC (QI	JADR	UPL	ENA	ND G	iATE)			
(	Q1						2SD	500F	,KF		TRAN								
(	Q2 <b>–</b> 5			1		1	2SA	608E,	,F		TRAN						ł		
(	Q6						2SC5	536E,	,F		TRAN								
	<b>Q</b> 7					1		608E,	•		TRAN						1		
•	Q8-10	)					2SC	536E,	,F		TRAN	ISISTO	R				1		
	Q11,1:						2SA	608E	,F		TRAN	SIST	R				1		
1	Q13,14	4					2SC	536E,	,F		TRAN	ISISTO	R						
	LED1			24	4		SLP-	540D	)		LED (	RED/	GRN	)					

### **BC-11 BLOCK DIAGRAM**

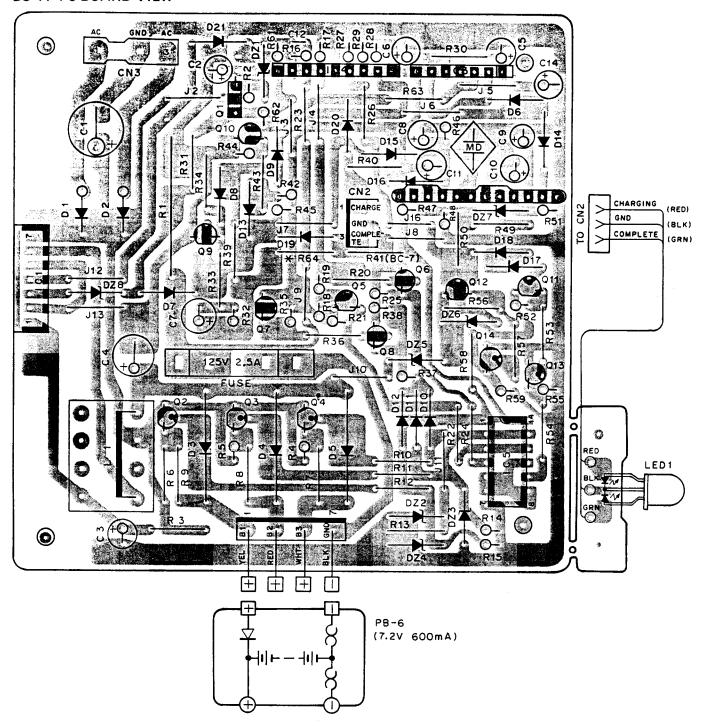








### **BC-11 PC BOARD VIEW**



Q1: 2SD600F,KF Q2-5,7,11,12: 2SA608E,F Q6,8-10,13,14: 2SC536E,F IC1: STK772B IC2: KCH-1003 IC3: AN6780 IC4: LA6393S IC5: LC4011B

D1-5: DSA26B D6-16,19-21: DS442

DZ1: GZA11Y DZ2-4: GZA10Z DZ5: GZA2.0X DZ6: GZA5.6X DZ7: GZA7.5Y DZ8: GZA3.0X

2SA608E 2SA608F

2\$C536E 2\$D600F 2\$C536F 2\$D600KF

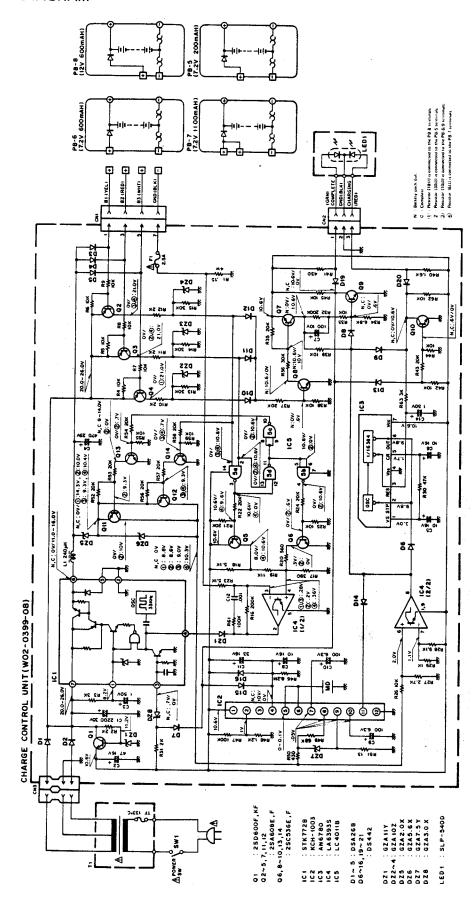


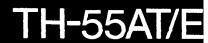
LC4011B

LA6393S



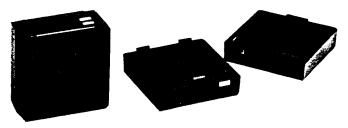
### **BC-11 CIRCUIT DIAGRAM**





### BT-6 (AAA MANGANESE/ALKALINE BATTERY CASE)/ DC-1 (DC ADAPTER)

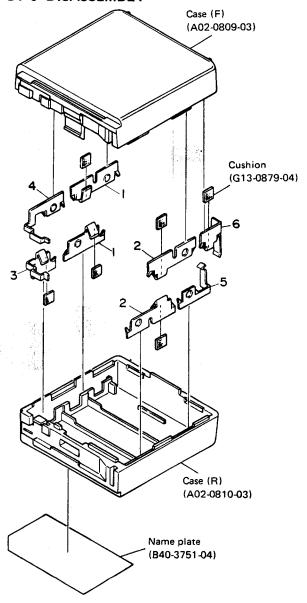
### BT-6 EXTERNAL VIEW



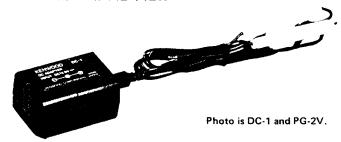
**BT-6 PARTS LIST** 

			* : New Parts
Ref. No.	New Parts	Parts No.	Description
1	*	E23-0496-04	Terminal A
2	*	E23-0497-04	Terminal B
3		E23-0498-04	Terminal C
4		E23-0499-04	Terminal D
5	•	E23-0500-04	Terminal E
6		E23-0601-04	Terminal F

**BT-6 DISASSEMBLY** 



### DC-1 EXTERNAL VIEW



### DC-1 PARTS LIST

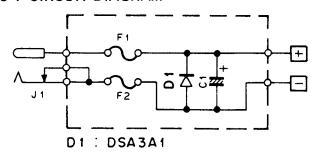
			* : New Parts
Ref No.	New Parts	Parts No.	Description
C1		CW04EW1C102M	Electro 1000µF 16WV
J1		E03-0165-05	DC jack
		F06-3026-05	Fuse (3A)
	•	J13-0410-05	Fuse holder

Diode

### DC-1 CIRCUIT DIAGRAM

D1

DSA3A1



### DC-1 SPECIFICATIONS

### Electrical characteristic

Max. input voltage	6V
Max. current	2A
<b>Dimensions</b> 58 W x 36.5 H x 29.5 D (m	nm)
Weight	40g